

## **ABSTRACT**

**Hardin, Craig William.** Fixed Abrasive Diamond Wire Saw Slicing of Single Crystal SiC Wafers and Wood. (Under the direction of Dr. Albert Shih)

This study investigates the effects of process parameters on fixed abrasive diamond wire saw machining. The effects of wire speed, rock frequency, and downfeed rate on cutting forces and surface roughness are studied during diamond wire saw slicing of single crystal SiC wafers. This study also investigates the machining of wood with oscillatory and looped style wire saws. The effects of feed rate, wire speed, coolant, and grain orientation on the cutting forces and surface roughness are studied.

The design of the cutting experiments using three different wire saws are presented. The first experiment uses a Diamond Wire Technology Millennium spool-to-spool rocking motion diamond wire saw to machine single crystal SiC wafers. The next experiments use a Murg looped wire saw and a Model 7243 oscillatory wire saw from Well Diamond Wire Saws to machine pine and oak.

A data acquisition system was constructed to record cutting forces, and signal-processing techniques were developed for removing noise. The diamond wire performed well, and afterwards the machined surfaces of all materials were measured to determine their surface roughness. A scanning electron microscope was used to examine the SiC wafers. Finally, the results and the direction of future work in this area are discussed.

# **Fixed Abrasive Diamond Wire Saw Slicing of Single Crystal SiC Wafers and Wood**

by  
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A thesis submitted to the Graduate Faculty of  
North Carolina State University  
in partial fulfillment of the  
requirements for the Degree of Master of Science

**DEPARTMENT OF MECHANICAL AND AEROSPACE ENGINEERING**

Raleigh

2003

**APPROVED BY:**

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Chair of Advisory Committee

## **BIOGRAPHY**

Craig Hardin was born in Gastonia, North Carolina in April of 1980. He is the son of Bill and Gail Hardin. Craig enrolled at North Carolina State University in August of 1998. He spent four years pursuing his Bachelor of Science degree in Mechanical Engineering and co-oped at GKN Automotive along the way. He enrolled in the five year B.S./M.S. program in the final year of his undergraduate studies. He graduated with his undergraduate degree in May of 2002. Craig has spent the last twelve months pursuing a Master of Science degree in Mechanical Engineering under the guidance of Dr. Albert J. Shih. Craig is currently searching for a job, and is hoping to be gainfully employed soon after his graduation.

## **ACKNOWLEDGEMENTS**

I would like to thank some of the people who helped me conduct this research project. Dr. Albert J. Shih worked as my advisor to first set up the project and to help in every step of its completion. Richard Lemaster provided funding, support, and advice from the Wood Tooling and Machining Research Group. I would like to thank my family and friends for supporting me during my graduate studies. I would also like to dedicate this thesis to Hazel Hardin, who passed away during the writing.

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## NOMENCLATURE

<b>Symbol</b>	<b>Description</b>
$d_w$	Drum width on oscillatory saw
$l_w$	Distance between drums on oscillatory saw
$d_r$	Diameter of guide pulleys
$l_r$	Distance between guide pulleys
$\gamma_1$	Measured bow angle 1
$\gamma_2$	Measured bow angle
$q_1$	Wire bow angle 1
$q_2$	Wire bow angle 2
$\alpha$	Rock angle
$F_T$	Measured tangential cutting force
$F_N$	Measured normal cutting force
$T_1$	Tension in wire to right of workpiece
$T_2$	Tension in wire to left of workpiece
$f_T$	Specific tangential force
$f_N$	Specific normal force
$R_a$	Surface roughness

# 1 Introduction

Material costs are driving the need for a method of machining wood with a lower kerf loss. Fixed abrasive diamond wire saw machining was investigated for use in cutting various species of wood. Wood machining has been traditionally dominated by the use of saw blades. Fixed abrasive diamond wire developed for use by the semiconductor industry, and is significantly thinner than even the most advanced thin kerf saw blades. This can lead to significant material cost savings in a production environment.

Single crystal SiC is becoming an important electronic ceramic for blue and green laser diodes, high power semiconductors, microwave and RF power transistors, and optoelectronic applications. Compared to Si, SiC is significantly harder and more difficult to slice into wafers that meet the tight warp and total thickness variation (TTV) specifications. The scratch marks and subsurface damages on the machined surface have been the concern of utilizing the diamond wire saw technology. The development and use of large, 200 mm and 300 mm (8 inch and 12 inch) diameter single crystal silicon wafers has also revitalized interest in wire saw machining technologies. Figure 1.1 shows the traditional inner diamond saw blade used to slice a single crystal silicon ingot into wafers. The thickness of the saw blade creates kerf loss, which is the material that is wasted due to machining. Wire saw machining technology, as shown in Figure 1.2, was developed for and applied to silicon wafer production in the late 90s to minimize kerf loss.

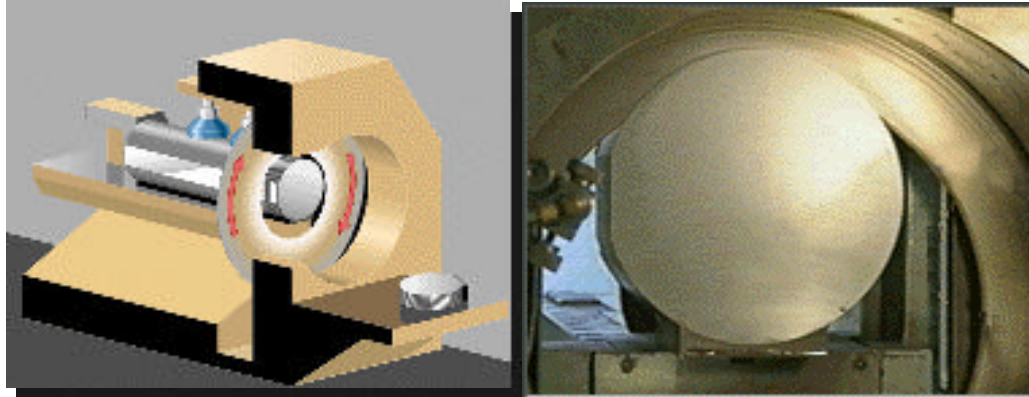


Figure 1.1: Traditional inner diamond saw blade for silicon wafer slicing. Mitsubishi [1]

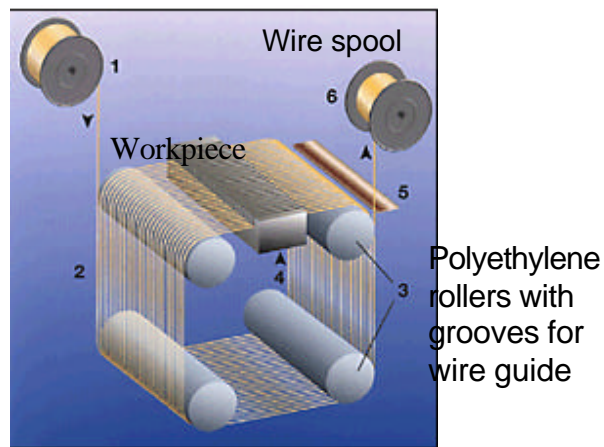


Figure 1.2: An illustration of wire saw machining a wafer. Bekaert[2]

## 1.1 Fixed Abrasive Diamond Wire

There are many different methods to produce fixed abrasive diamond wire. Every manufacturer uses a slightly different method. The diamond wire used has a steel core, which varied in size from 0.22 to 0.50 mm in diameter. This experiment utilizes two different types of wire. The SiC machining experiment uses a 0.22 mm nominal diameter, 25  $\mu\text{m}$  nominal size diamond grit, electroplated bond, and a steel core wire. Winter/Saint-Gobain manufactured the wire used for the SiC. A SEM micrograph of the wire used in the SiC experiments is shown in figure 1.3(a). Figure 1.3(a) shows the 25  $\mu\text{m}$  diamond abrasive

in the wire. The pine and oak machining experiments used two types of wire from Well Diamond Wire Saws. Well Diamond Wire Saws uses a stainless core, and then has a bonding layer that diamonds are effectively rolled on to. The diamond size was 64  $\mu\text{m}$ , and both 0.3 mm and 0.5 mm core wires were used. The high wire speed wood experiments utilized a new technology of a continuous looped wire. Well Diamond Wire Saws manufactures the looped wire in their typical fashion of rolling on the diamonds, and then laser welding the two ends together to form one continuous loop. Table 1.1 contains all of the data on the diamond wire used in each experiment. A SEM micrograph of a Well Diamond Wire Saws wire is shown in Figure 1.3(b).

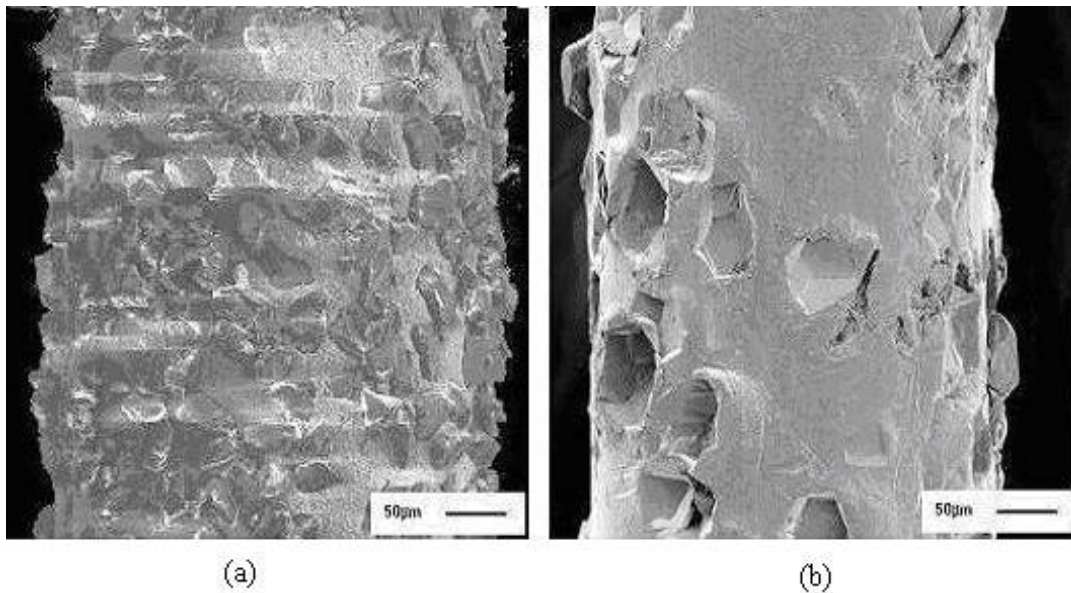


Figure 1.3: SEM micrographs of fixed abrasive wire: Winter/Saint-Gobain (a) and Well Diamond Wire Saws (b).

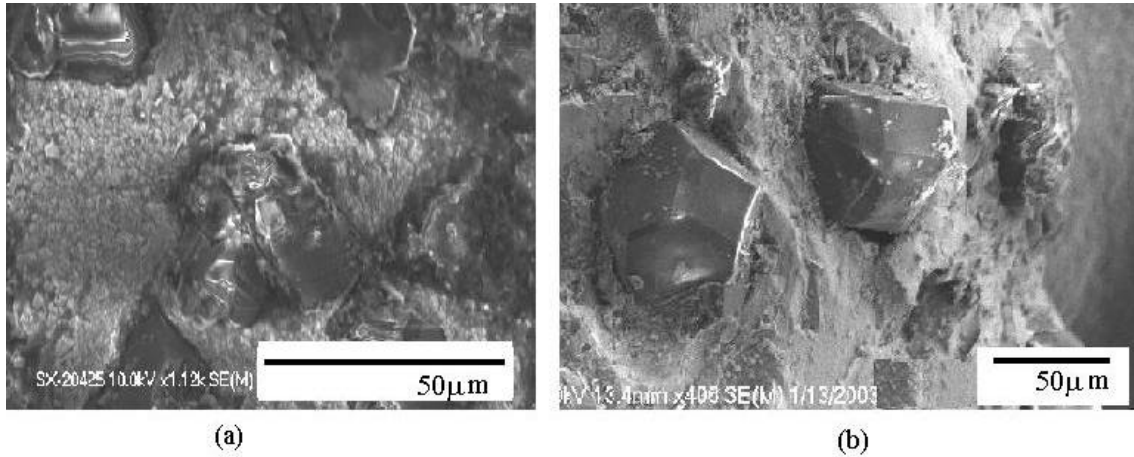


Figure 1.4: Diamond abrasive on: Winter/Saint-Gobain(a) and Well Diamond Wire Saws(b).

Table 1.1: Diamond wire data.

	<b>Winter/Saint-Gobain</b>	<b>Well Standard Wire</b>	<b>Well Continuous Loop</b>
<b>Experiment</b>	SiC tests 1 and 2	Oak and Pine; Rip and Crosscut	Oak and Pine; Rip and Crosscut
<b>Core Material</b>	Steel	Stainless Steel	Stainless Steel
<b>Core Diameter</b>	0.2 mm	0.5 mm	0.3 mm
<b>Diamond Grit Size</b>	25 μm	64 μm	64 μm
<b>Manufacturing Method</b>	Electroplating diamonds with a nickel layer	Mechanically affixing the diamonds to wire	Mechanically affixing the diamonds to wire, laser weld ends to form loop

## 1.2 Advantages of Diamond Wire Machining

Fixed abrasive diamond wire has two advantages over conventional wood machining. It has a very small diameter, which allows for an extremely small kerf loss. It also has the advantage of being able to make complicated contour cuts.

### 1.2.1 Thin Kerf

For wood, fixed abrasive diamond wire has the capability to replace many applications in thin kerf circular saw and band saw machining. Diamond wire machining has a much smaller kerf loss than any conventional wood cutting applications. A typical thin kerf saw requires a very accurate spindle and precision controls. The best thin kerf saw can only produce a kerf loss of 1mm. Fixed abrasive diamond wire can produce a kerf loss at least two times smaller. Figure 1.5 compares various thin kerf saws and the diamond wires used in this experiment.

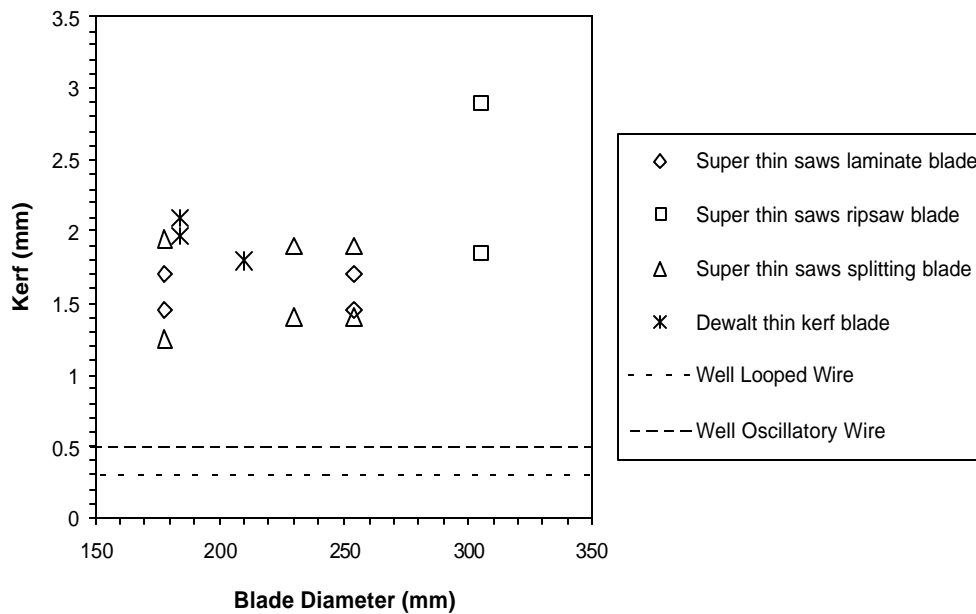


Figure 1.5: Kerf comparison in circular and diamond wire saw machining.





wire saw machining of a silicon wafer. Sahoo, et al. [7] applied the finite element method to analyze the vibration modes in wire saw cutting of thin wafers. Bhagavat and Kao [8] and Bhagavat, et al. [9] presented the finite element analysis of elasto-hydrodynamic interaction in free-abrasive diamond wire machining. Clark, et al. [10,11] present analysis of process monitoring, and wood machining of diamond wire machining.

Most of the breakthroughs in wire saw technology are documented as patents. A survey was conducted on wire saw related patents in the United States. A process for cutting brittle semiconductor materials with a diamond wire saw was first developed by H. Mech [12,13] in the 1970s. There are only three patents in the 1970s [12–14] and two patents in the 1980s [15,16] on the wire saw related machining technology. The number of patents increased slightly before the mid 1990s [17–20] and significantly increased after 1998. Further developments are shown in patents granted in 1998 [21–25], 1999 [26–29], 2000 [30–39], 2001 [40–45] and 2002 [46-50].

This review demonstrates that wire saw machining remains a proprietary technology and there is a lack of research on fixed abrasive diamond wire saw machining. With the needs for continuous improvements in semiconductor, ceramic, and woodworking industries, new diamond wires and wire saw machines are expected to continue evolving to achieve more precise, efficient, and cost-effective machining.

## **2 Experiment Design and Setup**

This chapter describes how the experiments were performed. It includes sections describing the equipment used to conduct the experiments and the materials the experiments were conducted on. There is also a section describing how the process parameters were chosen to form the testing matrixes.

### ***2.1 Equipment Utilized***

Many tools were used in this study to perform the experiments and to analyze the results. The following sections describe the major equipment used such as the wire saws, the fixed abrasive diamond wire used in each experiment, components in the dynamometer system, the scanning electron microscope used, the scanning acoustic microscope used, and the devices used to measure surface roughness.

#### **2.1.1 Diamond Wire Technology Diamond Wire Saw**

A Millennium Series rocking motion slicing fixed abrasive diamond wire saw was used in this study to machine the single crystal SiC. This saw utilizes the spool-to-spool model of cutting, where the wire reverses direction periodically. The machine possesses the ability to conduct rocking motion cutting at three speeds (slow 0.15 Hz, medium 0.30 Hz, and fast 0.50 Hz) at up to 6 degrees of wire rock. The wire is run between two spools. The leading wire spool is connected to a motor that pulls the wire to produce the wire movement, and the trailing wire spool is connected to a motor that opposes this movement to provide a specified wire tension. When the wire travels fully from one spool to the other, the direction of wire movement reverses, switching the function of each motor between leading and trailing functions. Each spool also contains a buffer amount of wire, which helps the machine to run smoothly. The wire speed is user selectable for any speed between 2.5 and 15 (m/s). The wire tension supplied by the trailing motor is programmable between 13 and 50 N.

This wire saw slices by slowly feeding the wire into the workpiece. To achieve this, the whole wire yoke structure, including both wire spools and all four wire guide pulleys, is mounted on two vertical slides. The work piece remains stationary throughout the machining process. The stepping motor turns a ball screw, which drives the yoke mechanism up or down as a unit. The stepping motor has 240 steps per rotation, and its gearing results in 10 motor rotations for every 2.54 mm linear downfeed. The two methods of downfeed rate control are wire bow angle rate and specified linear downfeed rate. All of the tests performed in this experiment kept a constant linear downfeed rate, which was varied throughout the experimentation. For the bow angle controlled downfeed rate, the machine can be programmed to find a downfeed rate that causes a set wire bow angle of anywhere between 0.1 and 6 degrees. The specified linear downfeed rates are user selectable between 0.00127 and 0.635 (mm/s).

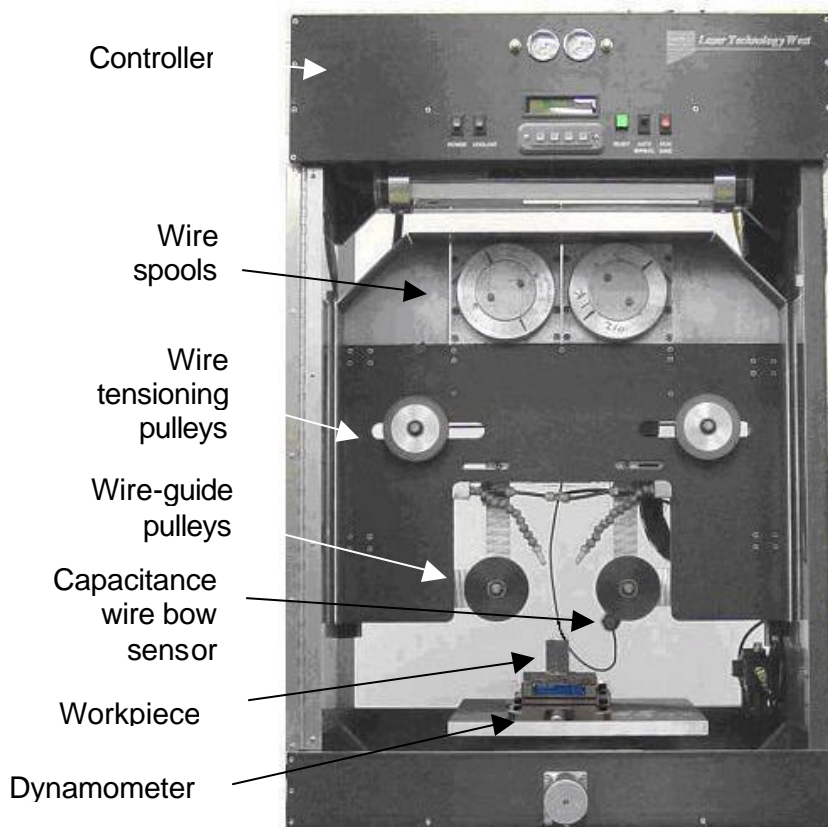


Figure 2.1: Wire saw used in this experiment.

### 2.1.2 Well Diamond Wire Looped Wire Saw

A Well Diamond Wire Saws Murg high-speed looped wire saw was used to machine oak and pine samples. The machine uses a 2.2m long piece of looped diamond wire. The looped wire saw has the ability to have wire speeds from 0.5 to 20 m/s. The wire travel is unidirectional, and is very similar to a band saw. The saw does not have any feed mechanism, or any other form of motion control. Figure 2.2 illustrates the wire saw motion where  $d_w$  and  $l_w$  are 394 and 481 mm respectively. :

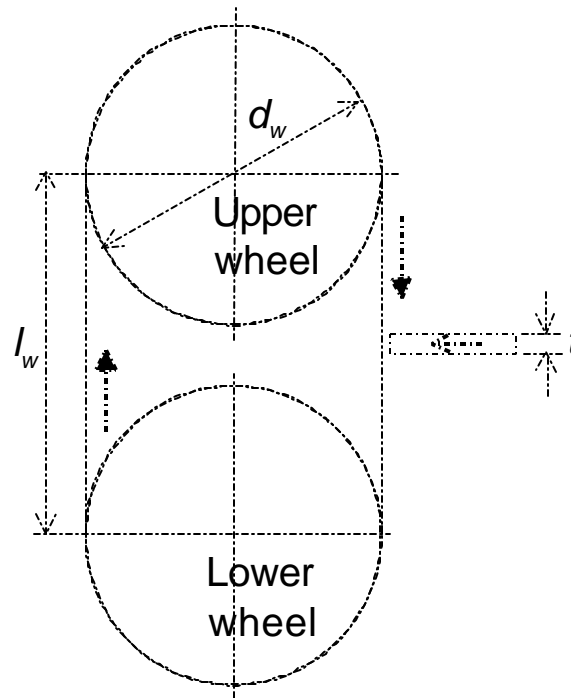


Figure 2.2: Looped wire saw diagram.

### 2.1.3 Well Diamond Wire Oscillatory Wire Saw

A Well Diamond Wire Saws model 7243 fixed abrasive oscillatory diamond wire saw was used to machine oak and pine samples. The machine uses a 40m long piece of 0.7mm

diamond wire. The oscillatory wire saw has the ability to have wire speeds from 0 to 1.5 (m/s). The wire travel is oscillatory, and is a cross between a conventional slicing saw and a scroll saw. The 40 m piece of wire runs from the upper drum to the lower drum, then the motion reverses. The drums have individual grooves cut in them for the wire to spool around. This way the wire does not ever come in contact with another section of wire. This can solve many problems associated with wire wear. Conventional wire saws wind the wire on spools, and the wire is constantly in contact with other pieces of wire. This can cause premature failure, and a decrease in overall machining effectiveness. Wire guides were installed on a series of cuts to see the benefit of keeping the motion of the wire more precise. The saw does not have any feed mechanism, or any other form of motion control. The user must feed the piece in manually. Figure 2.3 illustrates the wire saw motion where  $d_w$ ,  $l_w$ ,  $d_r$ ,  $l_r$  are 470, 927, 25, and 112 mm respectively.

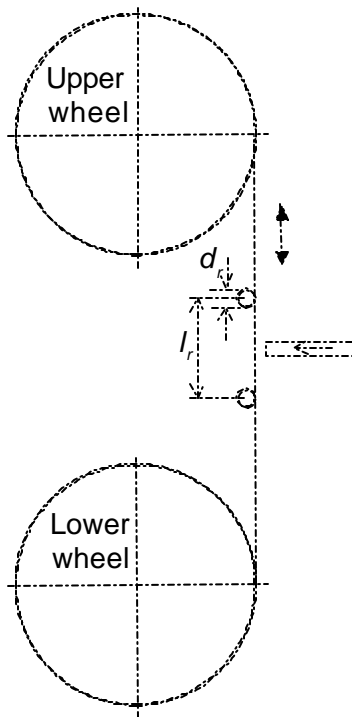


Figure 2.3: Oscillatory wire saw diagram.

#### 2.1.4 Diamond Wire

Three different types of fixed abrasive diamond wire were utilized in the machining experiments. Table 2.1 below shows the types and specifications of the different diamond wires and the experiments in which they were used. Winter/Saint-Gobain manufactured the wire used for the SiC. A SEM micrograph of the wire used in the SiC experiments is shown in Figure 2.4 (a). The pine and oak machining experiments used two types of wire from Well Diamond Wire Saws. The high wire speed wood experiments utilized a new technology of a continuous looped wire. A SEM micrograph of a Well Diamond Wire Saws wire is shown in Figure 2.4 (b).

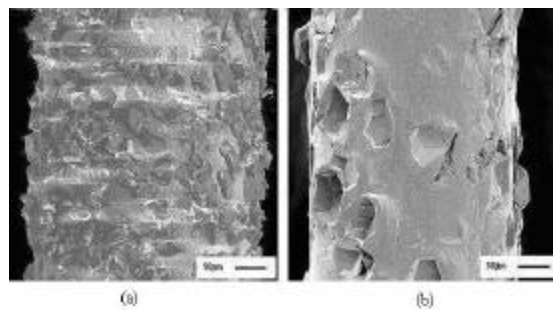


Figure 2.4: Winter/Saint-Gobain (a) and Well Diamond Wire Saws (b) fixed abrasive wire.

#### 2.1.5 Dynamometer

A Kistler brand model 9255B 3-axis force dynamiter was used to measure the cutting forces exhibited on the work pieces during cutting. The dynamometer signals were routed through a pair of Kistler 5010B single channel dual mode charge amplifiers with calibration factors of 3.76 and 7.85 pC per mechanical unit for the vertical and the two horizontal force channels, respectively. The dynamometer used is rated to record forces in the range of  $-5$  to  $5$  kN and above the threshold of  $0.01$  N. A Kistler 3-conductor armored cable was used to connect the dynamometer to a box. Coaxial cables were run from the terminals on the end of

the dynamometer cable to the charge amplifiers and were connected through BNC cable connectors.

### **2.1.6 Data Acquisition**

A National Instruments PC-based data acquisition system was used to record force signals from the dynamometer and the wire bow signal from the wire saw machine's controller. These signals were collected inside a National Instruments SCB-68 terminator block. A model 184749A-02 shielded cable connected the terminator block to a PCI-6035E model PC-based PCI data acquisition card. This card has a theoretical sampling rate of 200 thousand samples per second spread across 16 single ended channels. The card supports 8 channels if they are measured as differential signals.

### **2.1.7 Feed Mechanism for Wood Experiments**

The saws manufactured by Well Diamond Wire Saw do not have a changeable feed rate; therefore, the wood machining experiments required a feed mechanism to advance the work piece into the diamond wire. An Isel Automation linear unit was used. A programmable panther controller controlled it. The linear unit allowed for a variety of reliable feed speeds for all of the wood testing.

### **2.1.8 Scanning Electron Microscope**

A Hitachi S-4700 cold field emission scanning electron microscope was used to take SEM micrographs of the SiC wafers, diamond wire samples, and cutting debris. The voltage was set to 10 kV for every image. Some of the materials were non-conductive; therefore the

specimens required a coating layer of conductive material to produce good micrographs. A gold/platinum sputtering machine was used in these cases to coat the specimens.

### **2.1.9 Surface Roughness Measurement**

A Talysurf 120 contact stylus surface roughness measurement machine was used to obtain values for  $R_a$  for the machined SiC surfaces. This machine uses a diamond stylus to measure the height of the workpiece surface along a profile line. Each measurement used 60 consecutive 0.08 mm cutoff lengths for a listed overall profile length of 4.8 mm.

A Mitutoyo Surftest stylus system was used to determine the surface quality on the machined wood surfaces. This machine also uses a diamond stylus to measure the profile of the surface. Each measurement used a profile length of 2.4 mm.

## **2.2 Materials Used**

Cree Inc provided the single crystal SiC used in the cutting tests. The ingot is 3 in. in diameter. Single crystal SiC is an extremely hard, but brittle material. It has a hardness of 9 mohs, which is approximately 2035 HV. This hardness is what makes it quite challenging to machine. The first test utilized a flat-sided wafer. This ensures that the force data was accurate through the whole test, and that the wire contact area stays constant. The second test utilized a conventional 3in. round wafer, because the eventual goal is to manufacture the round wafers with diamond wire. This second test was performed to analyze the cutting forces as well as the surface roughness. Figure 2.5 shows the flat-sided SiC wafer, as well as the conventional 3in. wafer used in the second experiment.



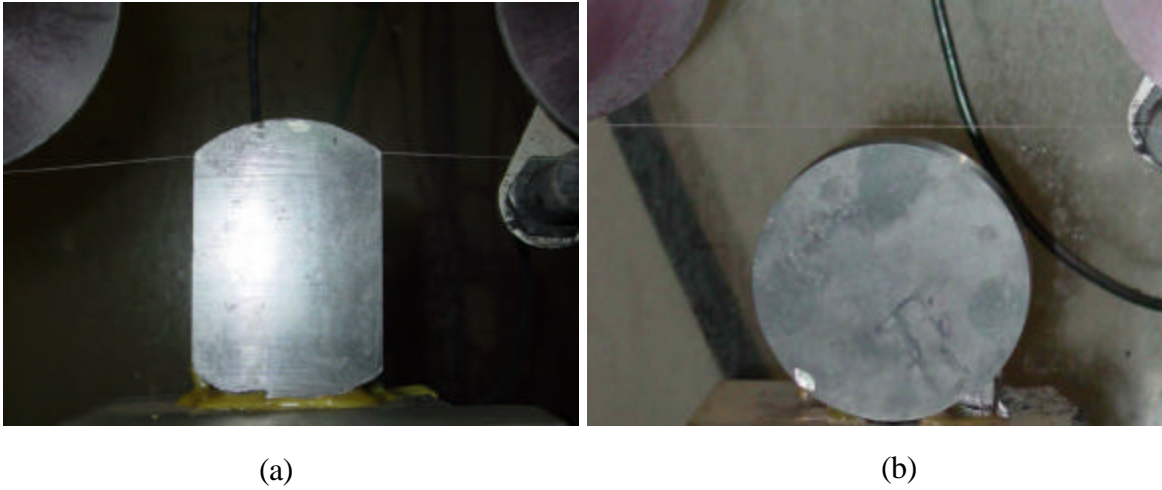


Figure 2.5: (a) Flat-sided and (b) conventional single crystal SiC wafers.

Pine and Oak wood materials were chosen as the main wood materials due to their high rate of use in industry. Pine is a common soft wood used in furniture products, and oak is a very commonly used wood. Every sample was an industry standard “one by” which is 19 mm (3/4”) in width. Figure 2.6 shows the pine and oak workpieces.

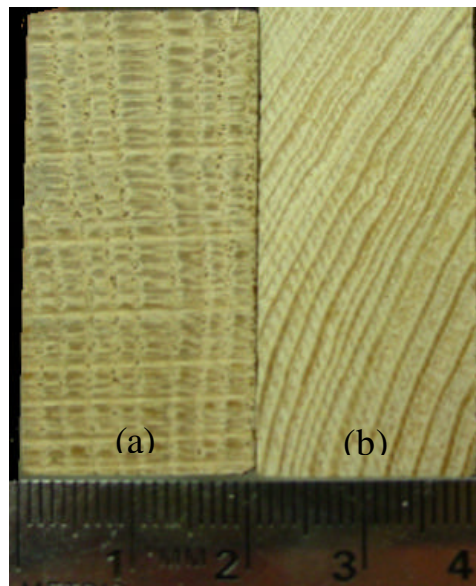


Figure 2.6: (a) Oak and (b) pine samples for machining.

## 2.3 Experiment Design

Three separate tests were designed. The single crystal SiC test was designed using the Diamond Wire Technology Millennium Slicing Saw. The wood testing was designed as a unit that could be placed on any wire saw that has vertically running wire. Every test was set up to measure cutting forces at various feed speeds.

### 2.3.1 Single Crystal SiC Experiment Design

The Millennium Series Slicing Saw was fitted with the force dynamometer, and the data acquisition system was setup and calibrated. An adapter plate was fabricated to serve as a mounting plate for the single crystal SiC. Figure 2.7 shows the complete assembly when mounted inside the wire saw.

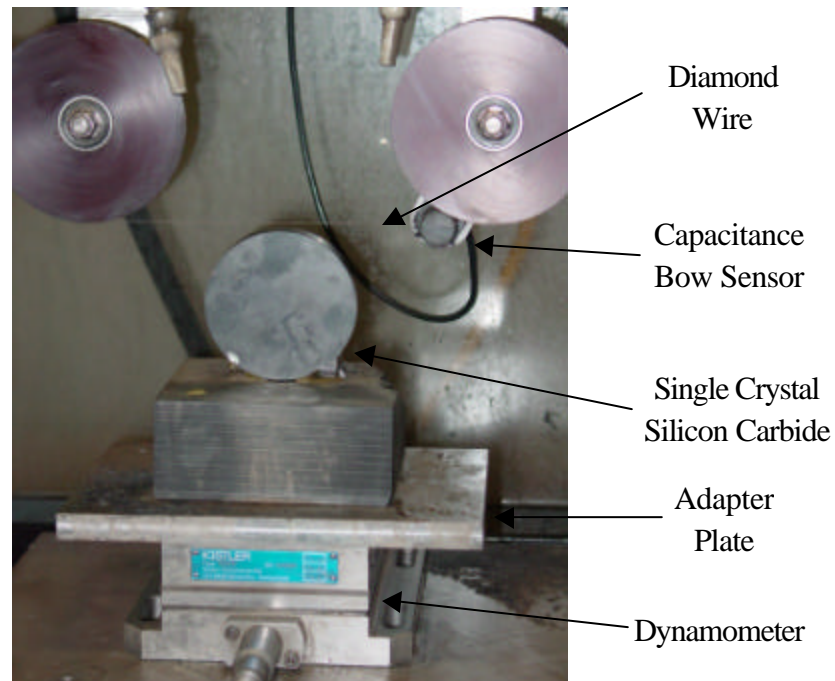


Figure 2.7: Single crystal SiC mounted inside of wire saw.

Test matrices were developed to test the effects of the downfeed rate, rocking frequency, and wire speed on the cutting forces and surface roughness. The first cutting test utilized the piece of single crystal SiC that had flat sides, while the second test utilized the conventional round wafer. The Diamond Wire Technology Millennium Series Slicing Saw has a variety of process parameters, but only a small amount of them were varied during the cutting experiments. The wire used in this experiment was already partially used. This is because diamond wire has a break-in period, where the forces greatly change as the diamonds are initially worn. This wire allowed us to accurately measure all of the forces, without experiencing any variation in the wire. The table below shows the process parameters that were held constant for the slicing tests on the flat-sided wafer.

Table 2.1: Constant process parameters in Experiment I.

Wire Length	185.928 m
Left and Right Buffer Length	45.7 m
Wire Velocity	10.16 (m/s)
Rock Angle	2 deg.
Rock Frequency	0.3 Hz
Wire Tension	22.24 N
Coolant	Water
After Cut Dwell	6 sec
Saw Retraction	Off

Cutting Experiment I was designed to test the effect of downfeed on the surface roughness. Therefore a set of three downfeed speeds were chosen for analysis. The following test matrix shows the varied parameters and their total cut depth into the workpiece.

Table 2.2 Experiment I test matrix.

Cut Number	Downfeed Rate (mm/s)	Cut Depth (mm)
1	0.0127	12 (7mm lead-in)
2	0.00508	5
3	0.00127	5

The second single crystal SiC test was set up to test the effect of rocking frequency and wire speed on the cutting forces and surface roughness of the SiC. This second test used new diamond wire. This test also looks at the effects of new wire, and its effective break-in period. The process parameters that were held constant for the second series of tests is below.

Table 2.3: Constant process parameters Experiment II.

Wire Length	185.928 m
Left and Right Buffer Length	45.7 m
Downfeed Rate	0.0127 (mm/s)
Rock Angle	2 deg.
Wire Tension	22.24 N
Coolant	Water
After Cut Dwell	6 sec
Saw Retraction	Off

Experiment II was designed to test the effect of wire speed and rocking frequency on the surface roughness. Therefore four rocking frequencies and three wire speeds were chosen for analysis. The following test matrix shows the varied parameters and their total cut depth into the SiC workpiece.

Table 2.4 SiC test 2 experimentation matrix.

Cut	Wire Speed (m/s)	Rock Frequency (Hz)	Cut Depth (mm)
1	10.16	0	13.35 (7mm lead-in)
2	10.16	0.15	6.35
3	10.16	0.30	6.35
4	10.16	0.50	6.35
5	8.128	0.15	6.35
6	8.128	0.30	6.35
7	8.128	0.50	6.35
8	11.18	0.15	6.35
9	11.18	0.30	6.35
10	11.18	0.50	13.35 (7mm lead-out)

### 2.3.2 Oscillatory Saw Experiment Design

The Well Diamond Wire Saws model 7243 oscillatory style diamond wire saw was fitted with the Isel Automation linear slide, the force dynamometer, and the data acquisition system. An adapter plate was fabricated to serve as a mounting plate for dynamometer. A top plate was also fabricated to clamp down on the workpiece as it is being machined. Figure 2.8 shows the complete assembly when mounted.

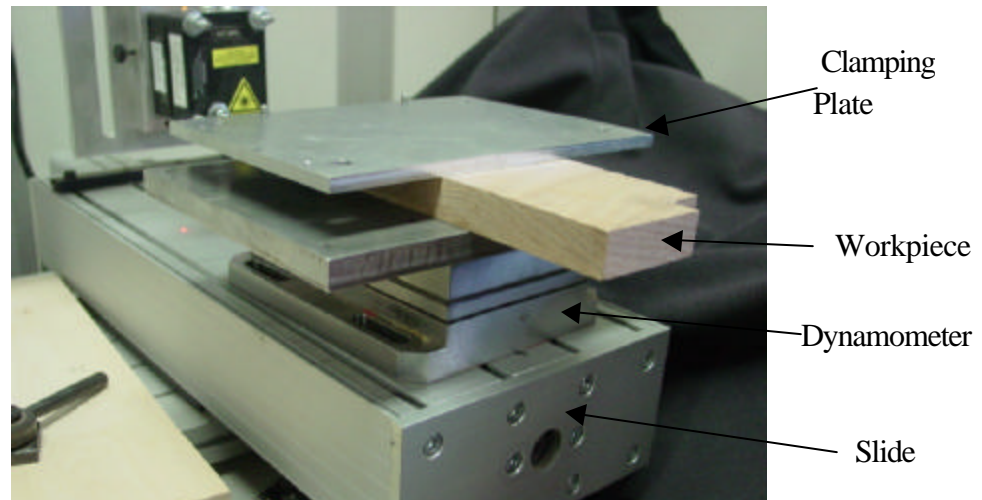
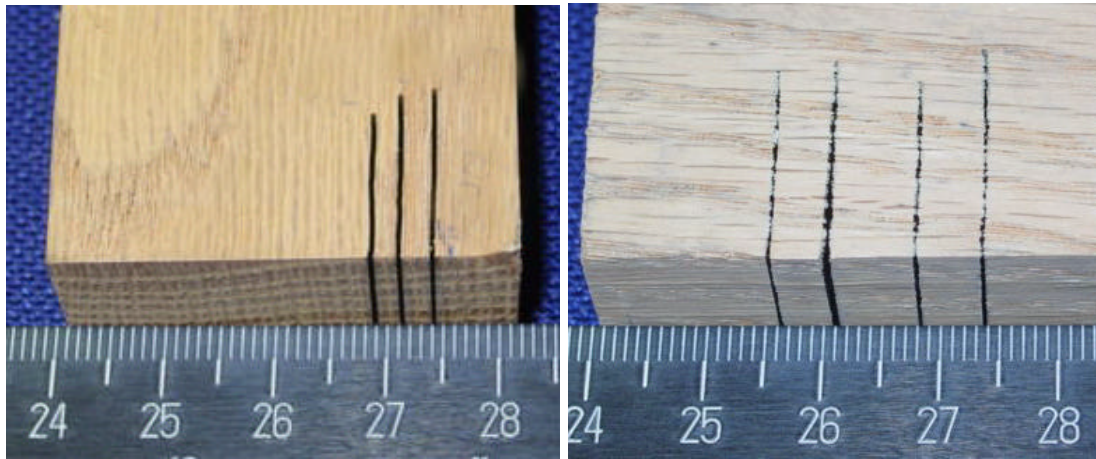


Figure 2.8: Wood machining setup.

Two different styles of cuts were investigated on the oscillatory wire saw. A rip is a cut that travels in the same direction as the grain; it is illustrated in Figure 2.9(a). A cross cut is a cut that travels across the grain structure, and is illustrated in Figure 2.9(b).



(a) Rip cut

(b) Cross cut

Figure 2.9: Two types of cutting for wood.

This experiment was set up to evaluate the surface roughness, as well as analyze the cutting forces. A 0.5mm nominal diameter Well fixed abrasive diamond wire with a 64  $\mu\text{m}$  diamond size was used in all of the experiments. A series of baseline cuts were run on the pine and oak samples. The baseline test matrix is shown below in the table.

Table 2.5 Oscillatory saw baseline test matrix.

Workpiece	Cut Type	Feed Speed (mm/s)	Wire Speed (m/s)
Oak	Rip (with guides)	0.5	0.5, 1.0, 1.5
Oak	Cross Cut (with guides)	0.5	0.5, 1.0, 1.5
Pine	Rip (with guides)	0.5	0.5, 1.0, 1.5
Pine	Cross Cut (with guides)	0.5	0.5, 1.0, 1.5

A series of test were then expanded from the baseline matrix. The first set of tests was to see the effect of wire guide pulleys that are close to the sample while it is being machined. The pulleys are 112 mm apart, and they keep the wire from deflecting during the machining

process. Figure 2.10 illustrates the wire guides. The guide pulleys were removed, and the cuts in table 2.6 were made to test the effectiveness of the guide pulleys.

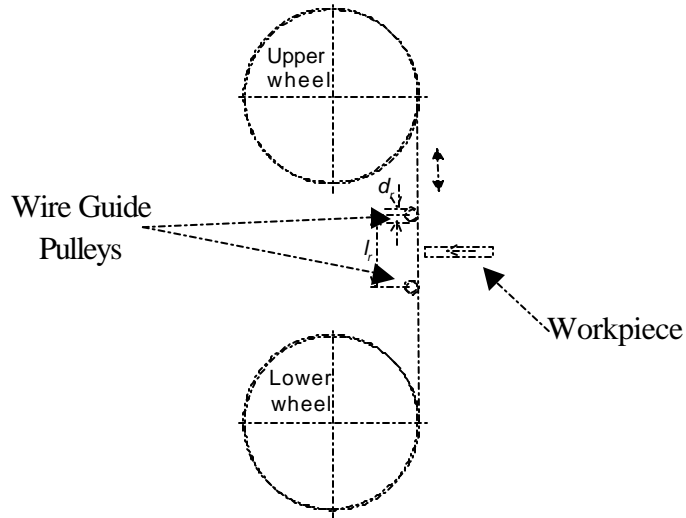


Figure 2.10: Oscillatory saw and the wire guide pulleys.

Table 2.6: Oscillatory saw wire guide pulley test matrix.

Workpiece	Cut Type	Feed Speed (mm/s)	Wire Speed
Oak	Rip (without guides)	0.5	0.5, 1.0, 1.5
Pine	Rip (without guides)	0.5	0.5, 1.0, 1.5

The second set of tests was designed to see the effects of the feed rate on the cutting force and the surface roughness. A cross cut was chosen for the second series of tests. The tests were run at three different wire speeds with both pine and oak. The test is shown in Table 2.7.

Table 2.7: Oscillatory saw feed speed test matrix.

Workpiece	Cut Type	Feed Speed (mm/s)	Wire Speed (m/s)
Oak	Cross Cut (with guides)	1	0.5, 1.0, 1.5
Pine	Rip (with guides)	1	0.5, 1.0, 1.5

### 2.3.3 Looped Wire Saw Experiment Design

The Well Diamond Wire Saws Murg model looped style diamond wire saw was fitted with the Isel Automation linear, the force dynamometer, and the data acquisition system slide as shown in Figure 2.8. The looped wire saw has such a high wire speed that it allows much higher feed speeds. A series of baseline tests were made at a variety of feed speeds. The test matrix in Table 2.8 shows the baseline tests that were designed.

Table 2.8 Loop wire saw baseline test matrix.

<b>Workpiece</b>	<b>Cut Type</b>	<b>Feed Speed (mm/s)</b>	<b>Wire Speed (m/s)</b>
Oak	Rip	0.5, 1, 1.5, 2	20
Oak	Cross Cut	0.5, 1, 1.5, 2	20
Pine	Rip	0.5, 1, 1.5, 2	20
Pine	Cross Cut	0.5, 1, 1.5, 2	20

Two sets of test were developed to compare to the baseline data. The first set of tests used a small amount of coolant to cool the wire. One problem that can occur while diamond wire machining is that the wire can become hot. The friction due to cutting produces large amounts of heat, which can cause premature wire failure. The set of tests were designed with a very small amount of coolant dripping on the wire while it machined the wood. The test parameters are shown in Table 2.9.

Table 2.9: Loop saw cross cut coolant test parameters.

<b>Workpiece</b>	<b>Cut Type</b>	<b>Feed Speed (mm/s)</b>	<b>Wire Speed (m/s)</b>
Oak	Cross Cut (with coolant)	0.5, 1, 1.5, 2	20
Pine	Cross Cut (with coolant)	0.5, 1, 1.5, 2	20

The second set of tests was designed to see the limits of the feed speed. It was set up to explore the limits of feed speed in looped wire saw machining. The feed speed is the most



important factor in wood machining, because that is what is limiting its application to wood.

Table 2.10 shows the set of parameters for the feed speed test.

Table 2.10: Loop saw cross cut feed speed test parameters.

<b>Workpiece</b>	<b>Cut Type</b>	<b>Feed Speed (mm/s)</b>	<b>Wire Speed (m/s)</b>
Pine	Cross Cut	0.5, 1, 1.5, 2, 2.5, 3, 3.5, 4	20

### 3 Wire Saw Machining Mechanics

A model has been developed to analyze the kinematics and cutting mechanics of the rocking motion used in the Diamond Wire Technology Millennium Series rocking motion slicing fixed abrasive diamond wire saw. The model also shows the balance of forces in diamond wire cutting.

#### 3.1 Kinematics of the Rocking Motion

The mechanism used to generate the rocking motion of the yoke in the diamond wire saw machine used in this study is shown in Fig. 3.1. Two pins in a circular arc slot are used to guide the yoke oscillating around a point, marked by A in Figure. 3.1, in the middle of the wire between two pulleys. A stepping motor drives a pinion on a circular rack gear to rotate the entire yoke assembly, including wire pulleys, the section of wire between two pulleys, and the capacitance sensor, around point A during cutting.

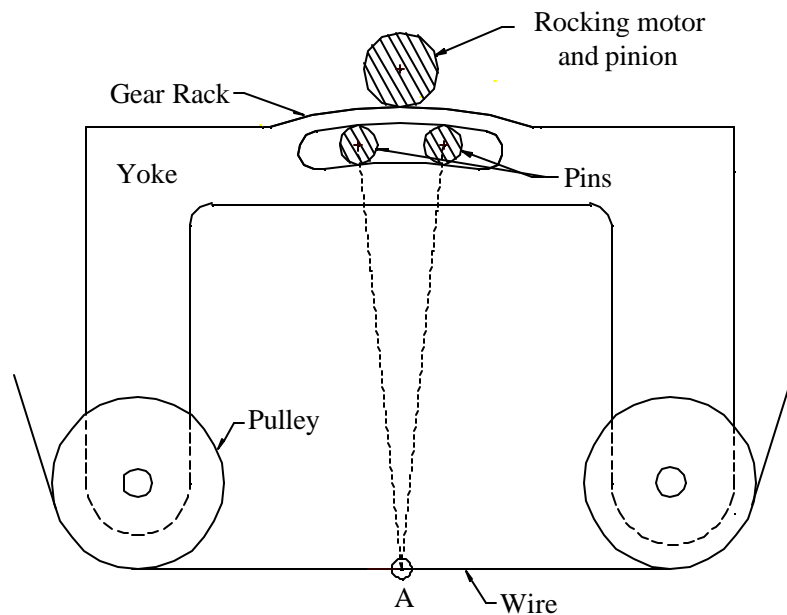


Figure 3.1: Kinematics of yoke rocking mechanism.

A capacitance sensor monitors the rocking motion. It uses a calibrated output voltage to monitor the rocking motion. Figure 3.2 demonstrates how the machine is calibrated, and shows the motion of the wire and pulleys.

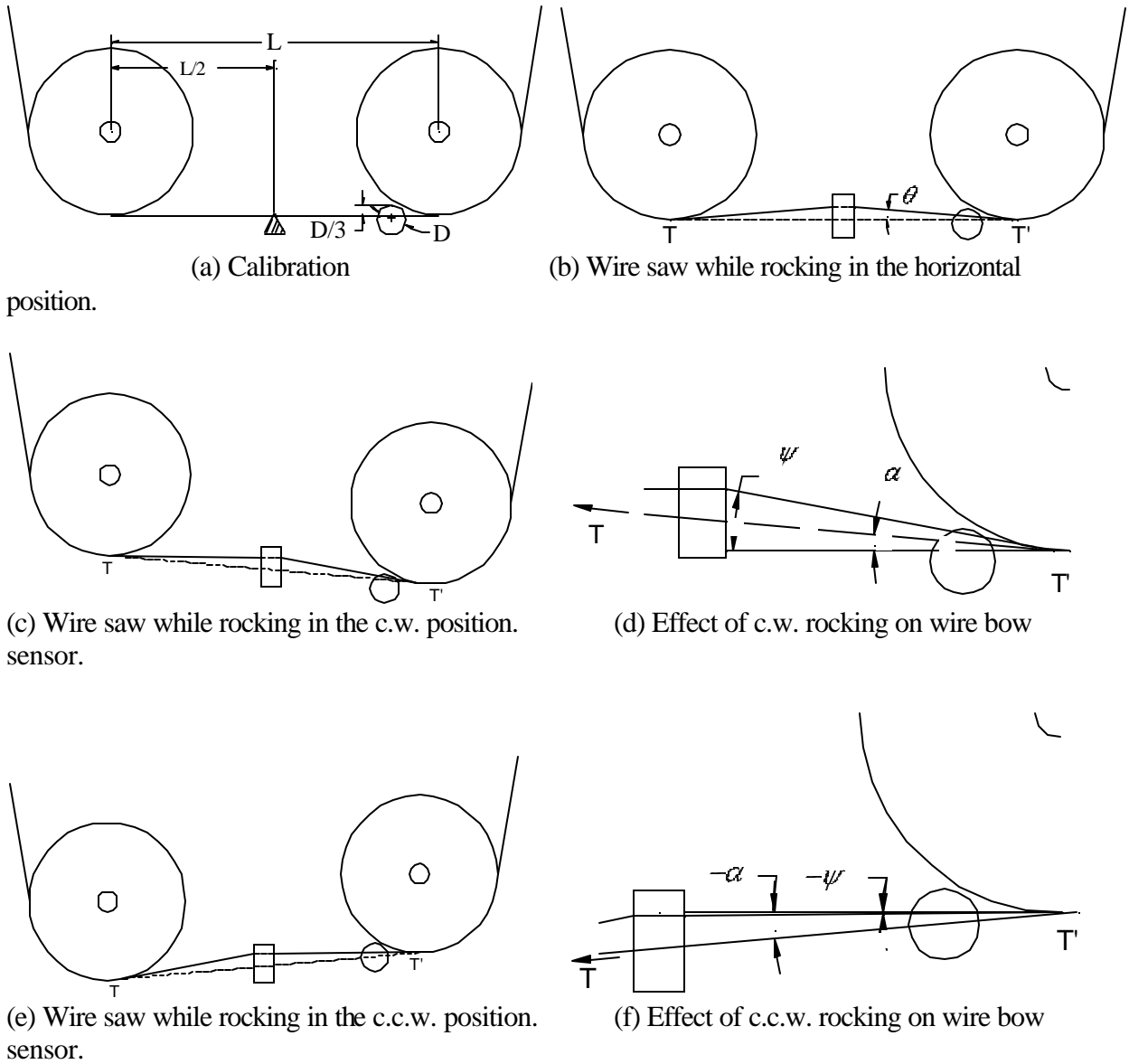


Fig. 3.2: The setup of capacitance wire bow sensor and the effect of rocking motion on wire bow sensor output.

### 3.2 Balance of Wire Cutting Force

Assume the cutting occurs in a narrow area and can be simplified as a point of contact. As shown in Figure 3.3, four forces are acting at the point of cutting, marked as B, on the wire. The  $F_T$  and  $F_N$  are the cutting forces. The wire tension forces are  $T_1$  and  $T_2$  acting in opposite directions. Under the small rocking angle assumption, two wire bow capacitance sensors, as shown in Fig. 3.3, are used to measure angles  $\mathbf{y}_1$  and  $\mathbf{y}_2$ , where  $\mathbf{y}_1 = \mathbf{q}_1 + \mathbf{a}$  and  $\mathbf{y}_2 = \mathbf{q}_2 - \mathbf{a}$ .  $\mathbf{q}_1$  and  $\mathbf{q}_2$  are the wire bow angles on both sides.

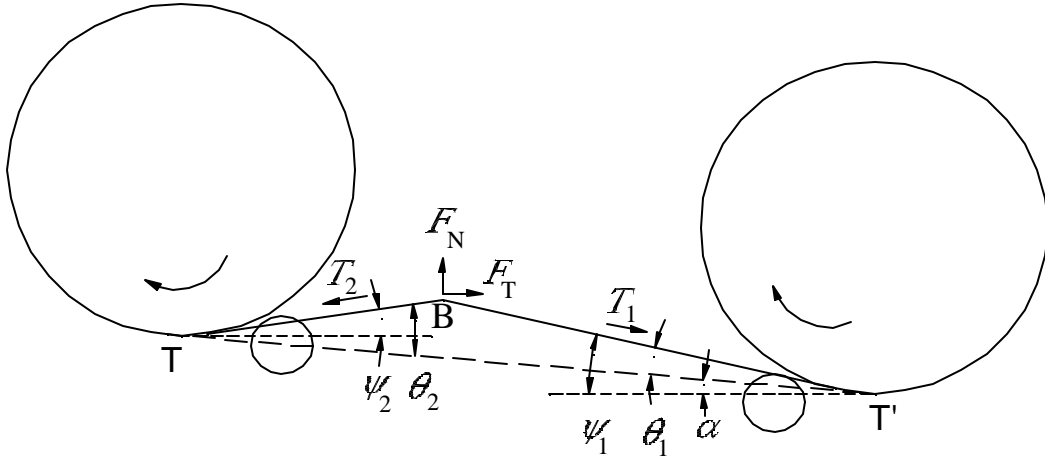


Figure 3.3: Force diagram of wire saw machining.

The balance of forces at point B can be expressed as:

$$\Sigma F_x = F_T - T_2 \cos \mathbf{y}_2 + T_1 \cos \mathbf{y}_1 = 0 \quad (1)$$

$$\Sigma F_y = F_N - T_2 \sin \mathbf{y}_2 - T_1 \sin \mathbf{y}_1 = 0 \quad (2)$$

Among the six variables in Eqs. (1) and (2),  $F_T$ ,  $F_N$ ,  $\mathbf{y}_1$ , and  $\mathbf{y}_2$  can be measured. A was dynamometer may be required to measure  $F_N$ . Wire tensions  $T_1$  and  $T_2$  can be isolated by rearranging Eqs. (1) and (2).

$$T_1 = \frac{-F_T \sin \mathbf{y}_2 + F_N \cos \mathbf{y}_2}{\cos \mathbf{y}_1 \sin \mathbf{y}_2 + \cos \mathbf{y}_2 \sin \mathbf{y}_1} \quad (3)$$

$$T_2 = \frac{F_T \sin \mathbf{y}_1 + F_N \cos \mathbf{y}_1}{\cos \mathbf{y}_1 \sin \mathbf{y}_2 + \cos \mathbf{y}_2 \sin \mathbf{y}_1} \quad (4)$$

When the cutting point B is in the middle of the wire section between two pulleys, as illustrated in Figs. 3.2(a) and 3.2(b),  $\mathbf{y}_1 = \mathbf{q} + \mathbf{a}$ ,  $\mathbf{y}_2 = \mathbf{q} - \mathbf{a}$ , and only one wire bow sensor is required.

## 4 Single Crystal SiC Machining Experiment 1 Results

The cutting forces and surface roughness of single crystal SiC machined by fixed a Diamond Wire Technology Millennium Series Slicing Saw are studied in this chapter. The effects of downfeed speed, wire speed, and rock frequency are investigated. Scanning electron microscopy is used to visually characterize the surface roughness, and compared to stylus profilometer measurement results.

### 4.1 Data Acquisition

In all, there were two signals measured by the data acquisition system used in this study. Of the three available force channels from the dynamometer, only the one channel measuring the force in the tangential direction,  $F_T$ , was used in every cut. The normal force was determined by acquiring the capacitance sensor signal, and then converting that voltage to a force. The force was calculated using the bow sensor calibration, and the normal force signal from the force dynamometer. Figure 4.1 is a diagram of the directions of the recorded forces. The following sections provide a brief description of each signal.

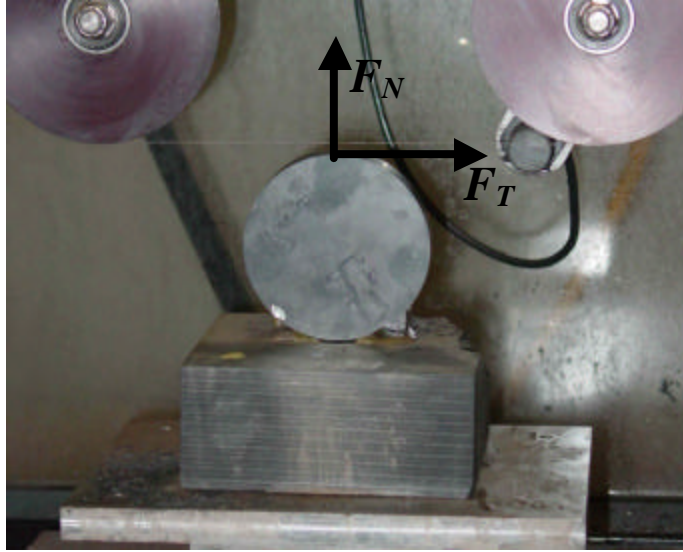


Figure 4.1: Diagram of cutting force directions.

#### 4.1.1 Tangential Force

The tangential cutting force,  $F_T$ , was calculated using the voltage output from the force dynamometer. The first step in acquiring  $F_T$  is calibrating the dynamometer. A scale was hooked up to the dynamometer, and then forces of 5, 10, 5, and 0 lbs. were applied. The following curve was generated during calibration.

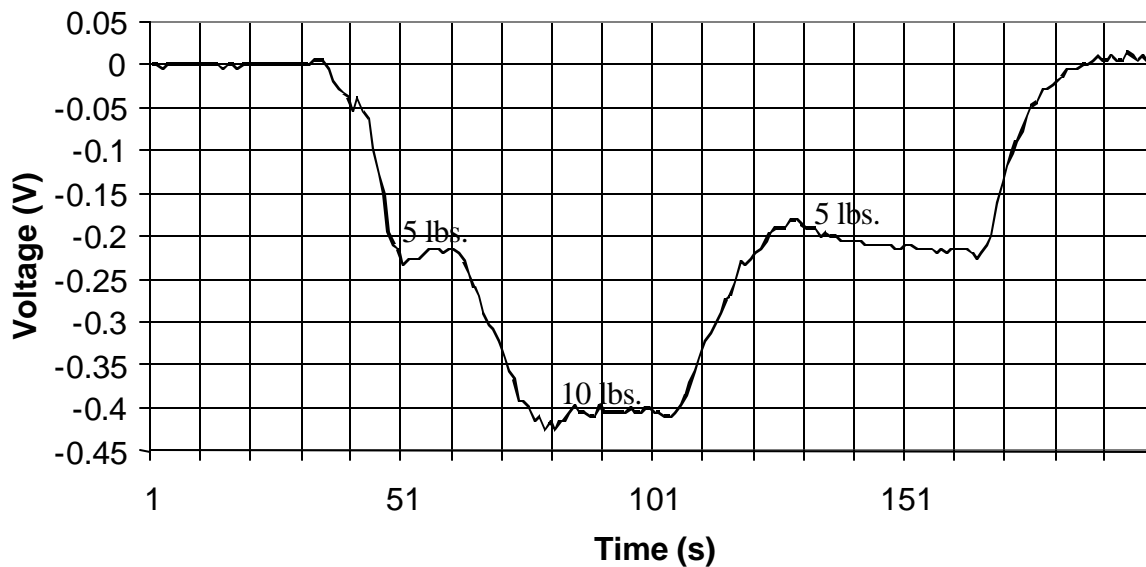
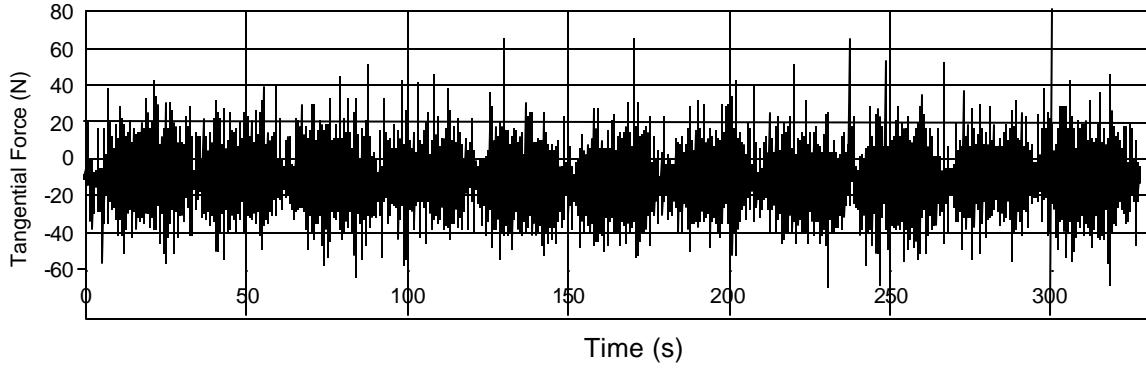


Figure 4.2:  $F_T$  calibration curve

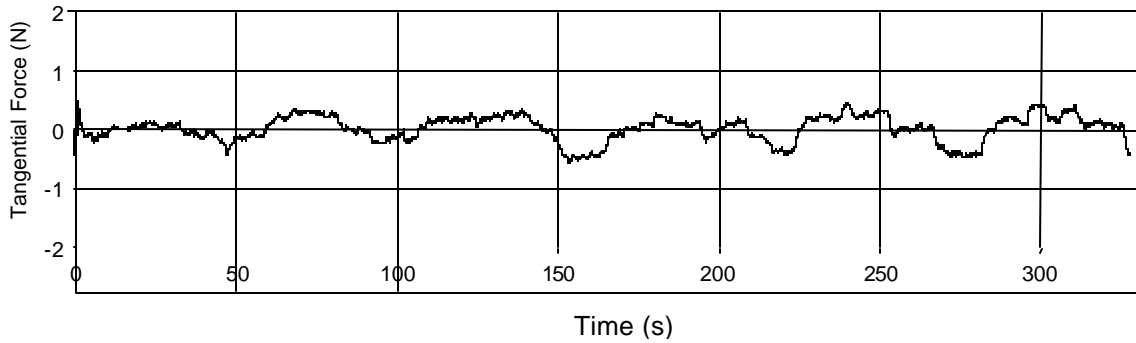
After the force plot was generated a calibration factor was developed. The average voltage gain for each weight was calculated then a final calibration factor was found to be 0.009125 (V/N). This factor was placed in the Labview program, which recorded the force data from the dynamometer and applied the calibration factor to the data. The first single crystal SiC test utilized a scan rate of 1000 (points/s). The forces do not change rapidly, so this rate is considered over sampling.

The raw data was imported into Dadisp™, which is a data analysis tool. A moving average was performed to remove the noise due to the charge amplifiers and cross talk between the channels. Over sampling the data allowed for moving averages to take every 1500 points and create an average from those. Figure 4.3 shows the raw data, and the data after the linear averaging.





**(a) SiC Cut 1\_6 Tangential Force as recorded**



**(b) Localized (1500 points) averaging**

Figure 4.3: Measured and locally averaged  $F_T$ .

After the linear averaging the tangential force was converted into a specific force. This force is similar to a pressure. Converting the force to a specific force allows every force to be compared, regardless of the length of cut. Equation (1) is an example of the conversion of a force to a specific force. The data was taken from the final cut with a downfeed speed of 0.0127 (mm/s), where  $t$  is 50 mm and  $W_D$  is 0.33 mm.

$$f_T = \frac{F_T}{t * W_D} \quad (1)$$

### 4.1.2 Normal Force

The normal force,  $F_N$ , is challenging to acquire, due to its small magnitude. A piezoelectric dynamometer is not able to sense a force that does not change over a long duration. The nature of a piezoelectric dynamometer is to sense dynamic forces, and the normal force is quite stagnant as well. The tangential forces change frequently due to the change in the wire direction, however the wire is constantly moving down, which creates a stagnant normal force. The magnitude of the force is also quite small, which creates problems. The bow capacitance sensor on the diamond wire saw was used to circumvent this problem. The first step in the process is to record the normal forces from the dynamometer while the bow sensor calibration is taking place. The method is similar to the method mentioned in [10], but it does not convert the voltage output to an angle before converting to a force. The Figure 4.4 shows the normal force on the dynamometer and the voltage from the capacitance sensor.

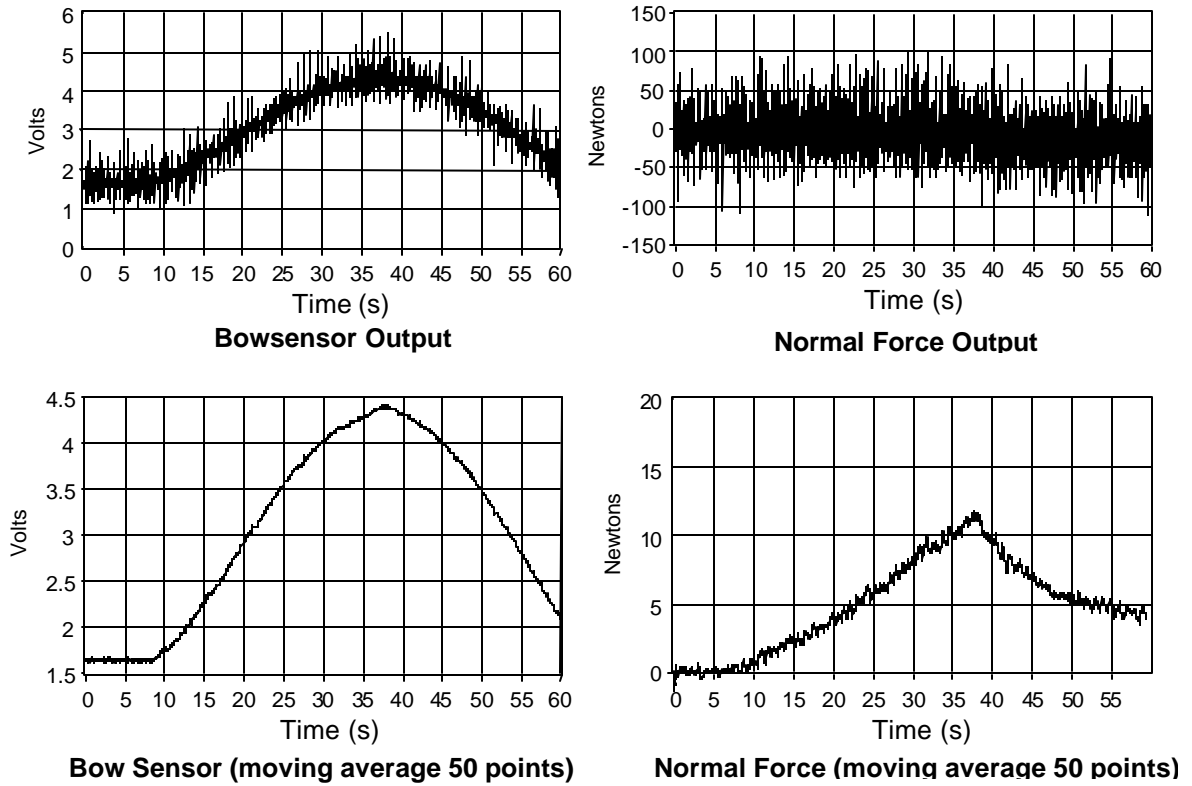


Figure 4.4: Bow sensor calibration plot.

This information gives a direct correlation from the voltage output to the force. A calibration curve was generated with the output data, and a third order polynomial was fit to the data. The calibration curve is below in Figure 4.5.

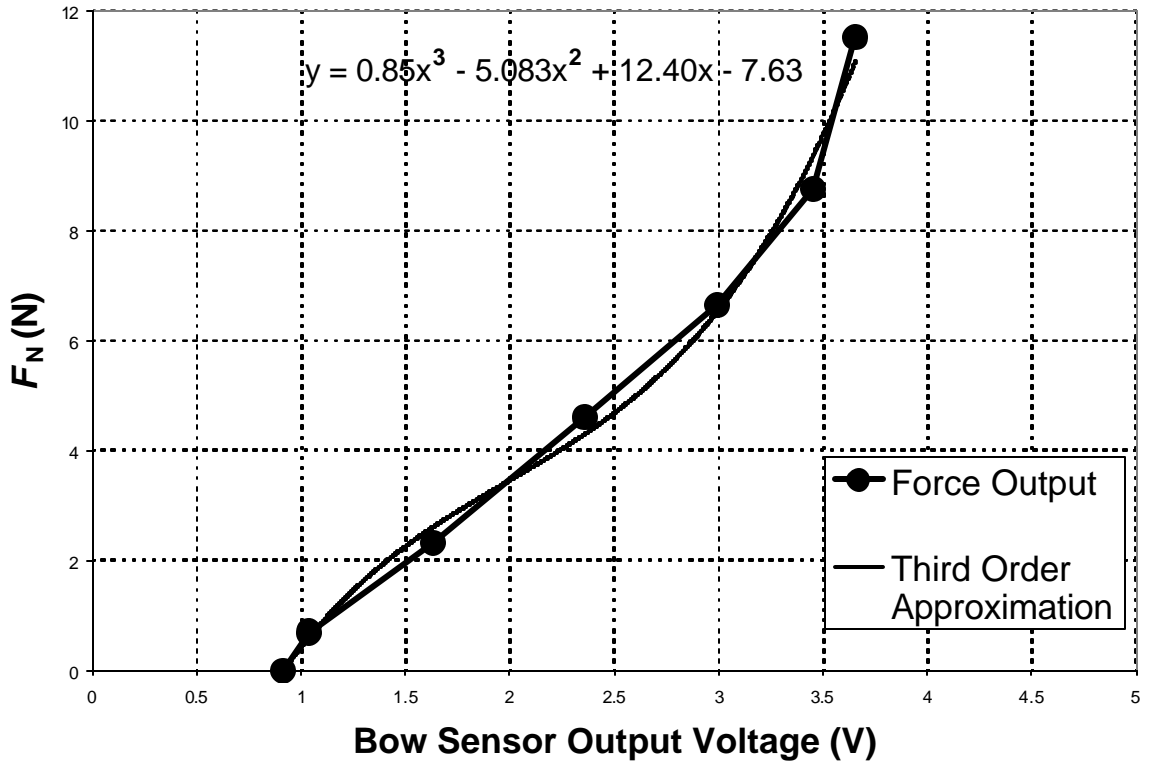
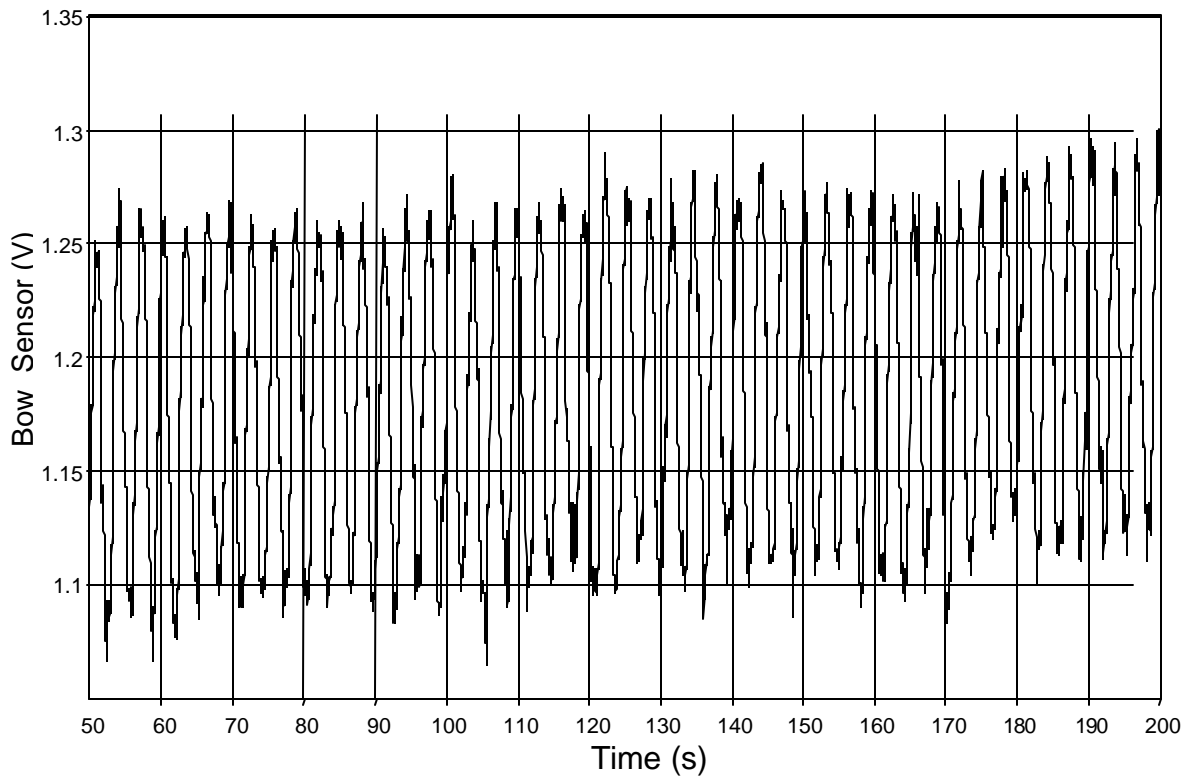


Figure 4.5: Bow sensor voltage to force conversion plot.

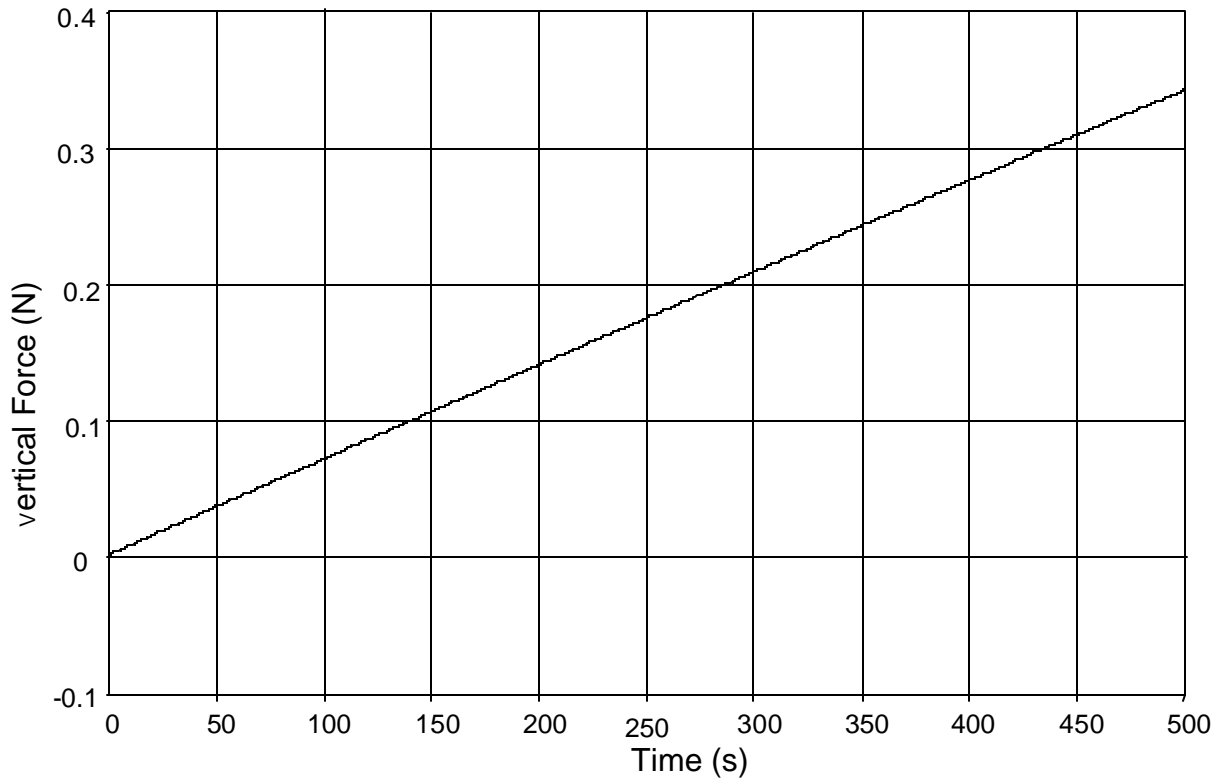
Due to the rocking motion of the wire saw, the output of the wire bow capacitance sensor is a sinusoidal plot, but it has a linear trend due to the increase in forces while machining. Figure 4.6 shows the output of the capacitance sensor while machining with a 0.15 Hz rocking frequency.



**Localized (50 Points) averaging**

Figure 4.6: Bow sensor output during machining with rocking motion.

The final step to acquiring the normal cutting force is removing the sinusoidal movement in the data, which is due to the rocking motion of the wire saw. A linear trend is taken from the data, which basically keeps the increase in the normal force, while removing the movement due to the rocking motion. The final data is shown below in Figure 4.7.



**Wire deflection converted to vertical force**

Figure 4.7: Final  $F_N$  output.

After the linear averaging the normal force was converted into a specific force. This force is similar to a pressure. Converting the force to a specific force allows every force to be compared, regardless of the length of cut. Equation (1) shows an example of the conversion of a force to a specific force. The data was taken from the final cut with a downfeed speed of .0127 (mm/s).

$$f_N = \frac{F_N}{t * W_D} \quad (1)$$

## ***4.2 Cutting Force and Surface Roughness Results***

The main objective of this test was to examine the cutting forces and surface roughness of the flat-sided single crystal SiC wafer. The downfeed velocity was varied as was discussed in the experimental setup. The test parameters were described in Table 2.2. After all of the data was processed, and the surface roughness was evaluated the following results were tabulated in figure 4.8.

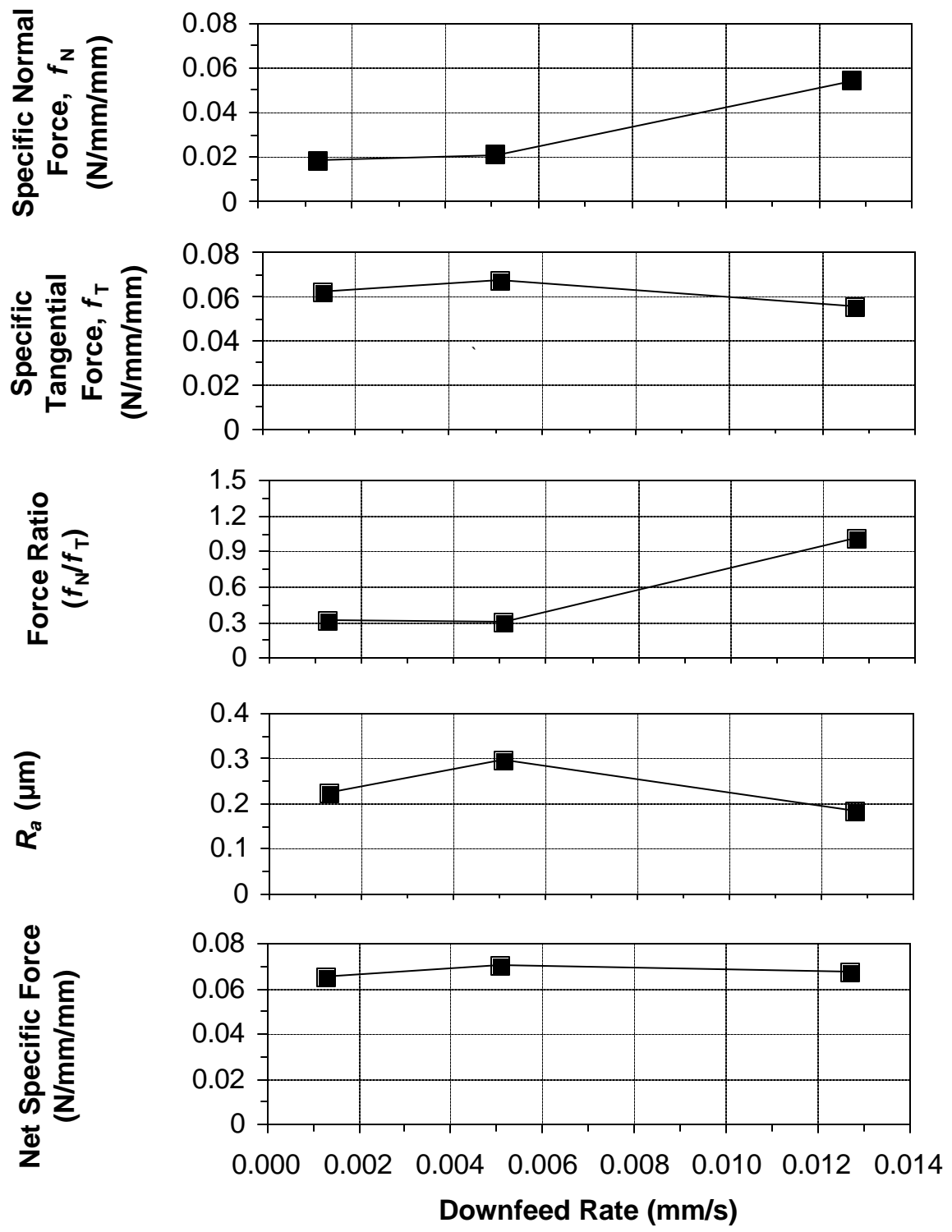


Figure 4.8: Experiment I cutting force and surface roughness results.



The specific normal force,  $f_N$  changed as expected. As the downfeed rate increased  $f_N$  increased as well. The normal force for the cut with the downfeed rate set at 0.0013 (mm/s) had a normal force of approximately 0.018 (N/mm/mm). As the downfeed increased,  $F_N$  increased as well. The fastest downfeed had the highest normal specific force, which was to be expected. The final specific normal force was 0.0540 (N/mm/mm). The downfeed was increased over the interval by a factor of 10, while the normal specific force increased by a factor of 3.5.

The specific tangential force,  $f_T$  changed in a different manner compared to the normal force. The force actually initially increased as the downfeed increased, but it actually decreased as the downfeed increased the final cut. The tangential force only varied by approximately 8%, but it still showed a trend that goes against conventional logic. This trend could likely be explained by a number of different circumstances. The most obvious is that the first cut that was made in the wafer was made at a downfeed rate of .0127 (mm/s). This cut also had the least tangential force, which goes against conventional logic. The possible explanation is that this cut had better access to the coolant, which can reduce cutting forces. The farther the cut is away from the top, the harder it is for the same volume of coolant to reach the cutting surface, and lubricate and cool the wire. The Figure 4.12 shows the coolant system, which could explain the tangential force phenomena.

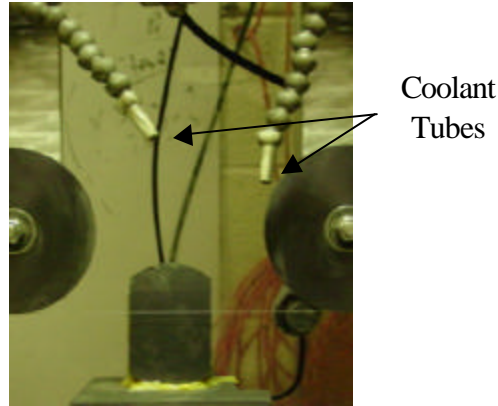


Figure 4.9: Coolant delivery system diagram.

The force ratio is also an important part of the cutting. The ratio varied from 1 to 4, but compared to the force ratio of 3 to 15 for CBN grinding of zirconia [51], 3 to 10 for CBN grinding of M2 tool steel [51], 4 to 9 for CBN grinding of silicon nitride [52], 5 to 5.5 for diamond grinding of silicon nitride [53], and 2 to 22 for diamond wire machining of SiC and TTZ foam ceramics [11], this force ratio is lower and may indicate more efficient material removal than traditional grinding.

The surface roughness is quite interesting. It seems to follow the same trend as the specific tangential forces. Every point corresponded directly with the specific tangential force. This is a very important finding, and it helped set up the second round of testing. The values of  $R_a$  varied from 0.18 to 0.29  $\mu\text{m}$ . The high level of feed speed did not seem to affect the surface finish. The surface roughness results also show the importance of the coolant while cutting, since it affects the tangential forces. The values are important while comparing to various other methods. The industry standard with a diamond slurry saw is 0.1  $\mu\text{m}$ , and the recorded values are quite close and show promise for the technology.

The net specific force just shows the trend of the magnitude of the forces. It follows the logical trend of increasing with increased feed speed. The net force is a good indicator of the

total magnitude as well, which can easily be overlooked while looking at individual force components.

### ***4.3 Scanning Electron Microscope Surface Characterization***

Scanning electron microscopy is a good way to visually characterize the surface roughness due to machining. There are a few major types of damage that are evident on the surface in the single crystal SiC. The first type of damage is called a stagnation line. Shown in Figure 4.10(a), it occurs when the diamond wire reverses direction. The wire saw never stops the downfeed, which places extra forces on the wire each time it stops and reverses direction. A line is clearly visible on the wafer whenever the wire reverses direction. The second type of damage is microcracking, which is shown in Figure 4.10(b). This is common whenever a very brittle material is machined. The final type of visible damage is surface pulverization, and is shown in Figure 4.10(c). This type of damage is characterized by deeper damage into the surface, and the material is visibly pulverized.

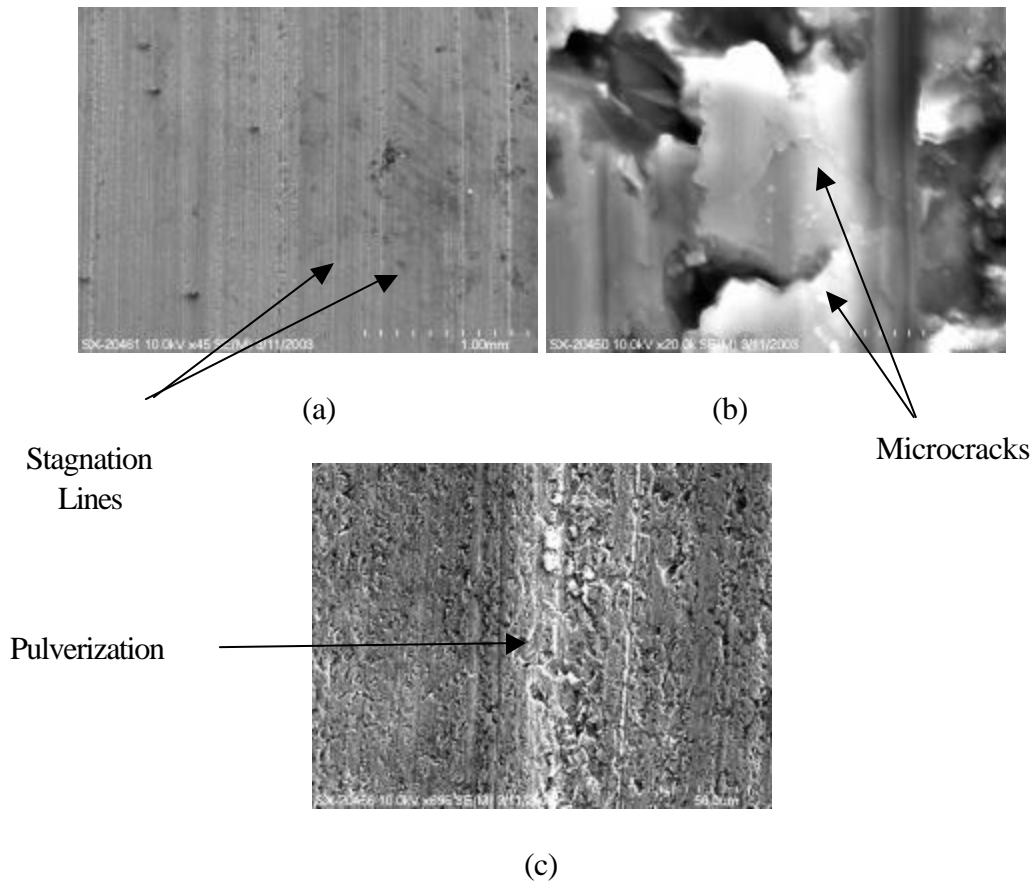


Fig. 4.10: SEM micrographs characterizing damage types.

The stagnation lines spacing varies with the downfeed rate and the wire length. The wire length stayed constant throughout the testing, so only the downfeed rate affected the spacing. The letter G in Figure 4.11(a) shows the spacing between the stagnation lines. The stagnation lines are 0.021mm apart. The wire length was 185.93 m, and the wire speed was 10.16 (m/s). Therefore, the wire changed direction every 18.3 seconds. The downfeed rate was 0.00127 (mm/s). Multiplying the downfeed rate and the time gives us a theoretical stagnation line spacing of 0.023 mm. This correlates with the real stagnation line spacing, but on the average the spacing is a small amount closer than the theoretical, which can cause forces to elevate over time. Figure 4.11 below gives a visual characterization of the wafer.

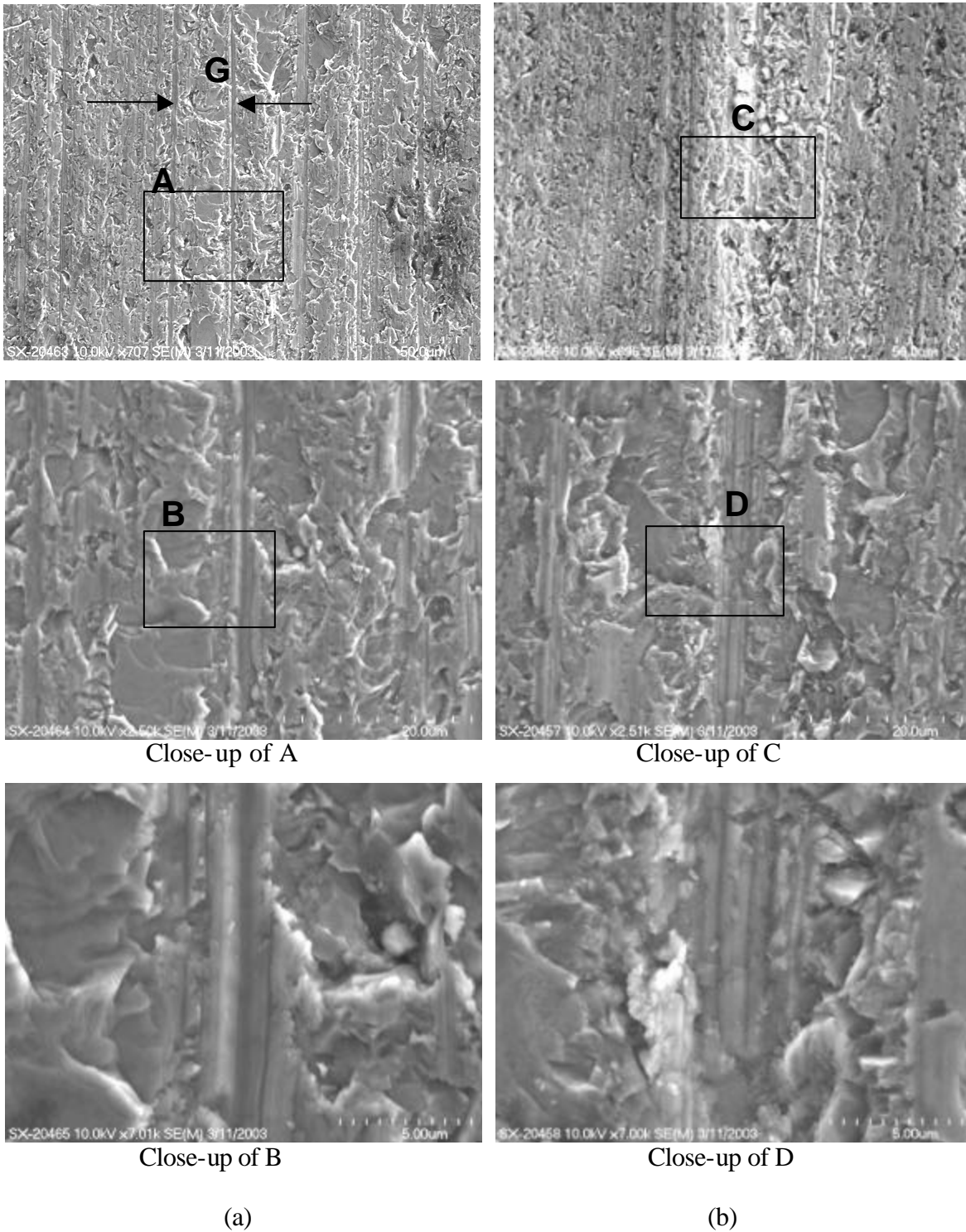
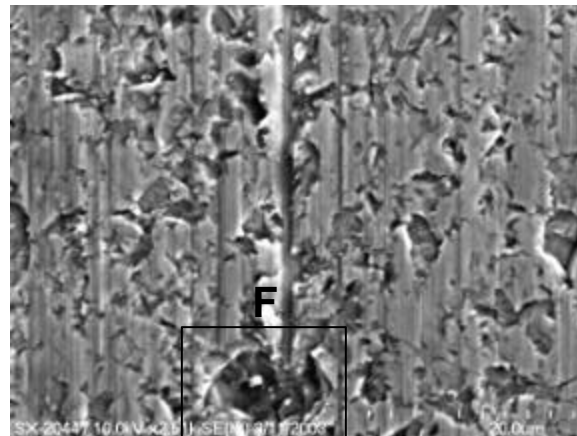
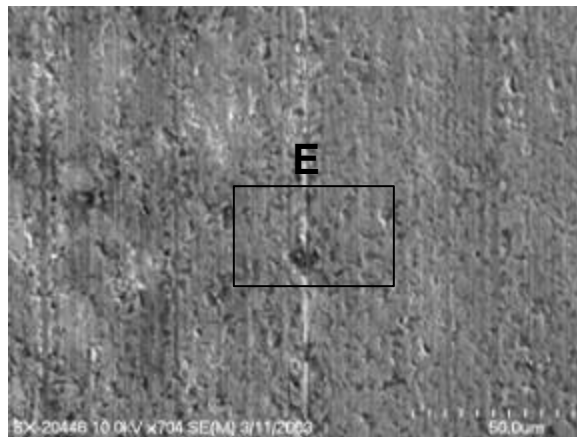
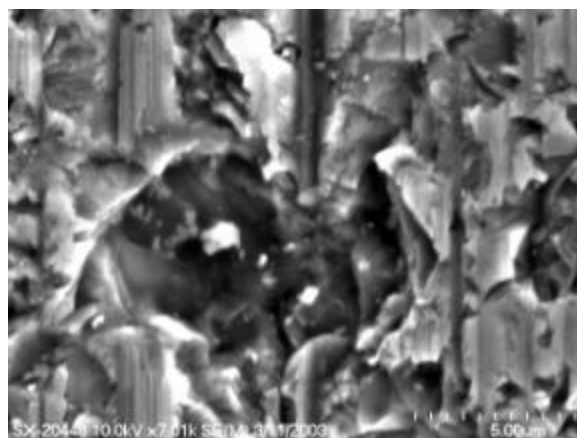


Fig. 4.11: SEM micrographs of machined SiC surface machined at (a) 0.00127 (mm/s), (b) 0.00508(mm/s).



Close-up of E



Close-up of F

(c)

Fig. 4.11: SEM micrographs of machined SiC surface at (c) 0.0127(mm/s). (cont.)

Figure 4.11(a) shows the damage at a stagnation line under the fastest of the three feed speeds. The series of pictures shows some microcracking, but not much pulverization. The stagnation lines are quite close together because with a slower downfeed the wire reverses directions many more times.

The second series of micrographs describes the damage done at 0.00508 (mm/s) downfeed. The difference in damage is quite noticeable along the stagnation lines. The lines are much farther apart, due to the faster downfeed, but there are large regions of pulverization and microcracking. The damage also appears to be much deeper as well.

Figure 4.11(c) characterizes the damage done with a downfeed rate of 0.00127 (mm/s). The damage done at this downfeed rate is quite evident. The biggest difference is the size of the cracks and the depth of the pulverization. The final micrograph zooms in on a large piece of SiC that was severely damaged. It is almost twice in size compared to any other damage found.

In summary the downfeed affects the damage to the wafer. The faster the downfeed rate is, the farther apart the stagnation lines are, but the damage is more severe. It appears to be a difficult balancing act.

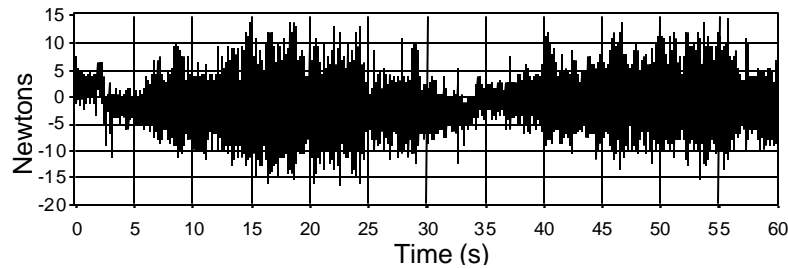
## 5 Single Crystal SiC Machining Experiment II Results

After completing the first experiment it was quite evident that the tangential force,  $F_T$ , is the driving force behind the surface roughness. The second set of tests was set up to evaluate the effects of new wire, rock frequency, and wire speed on surface roughness. Therefore, only the tangential force was examined in this experiment because it is the determining factor in the overall surface roughness. A conventional round wafer was used in this experiment because the ultimate application of wire sawing technology is machining complete wafers. A new wire was used in this experiment as well to investigate wire wear, and the forces associated with breaking in a new wire.

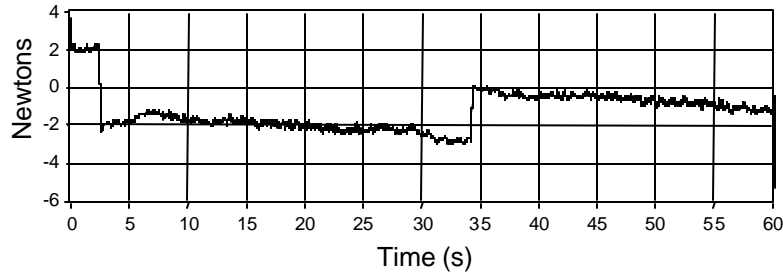
### 5.1 Data Acquisition

The first test showed that  $F_T$  was the most important force, so it was the only force investigated in this set of experiments. The only signal measured in this experiment was the tangential force. It was acquired in the exact same method that was explained in section 5.2.1, except a specific force was not calculated because the width of the wafer changes throughout the machining process. The plot below shows a typical tangential force during the second experiment.





**SiC Experiment 2 Cut 1 Tangential Force**



**Experiment 2 Cut 1 Tangential Force (200 Point Moving Average)**

Figure 5.1 Typical tangential force plots.

## ***5.2 Cutting Force and Surface Roughness Results***

There were essentially 10 tests that were performed while machining the round wafer. There were three different wire speeds, and three different rock frequencies. The other test was basically a baseline cut that had no rock frequency. Table 2.4 describes the process parameters varied for this test. After all of the data was processed, and the surface roughness was evaluated the following results were tabulated.

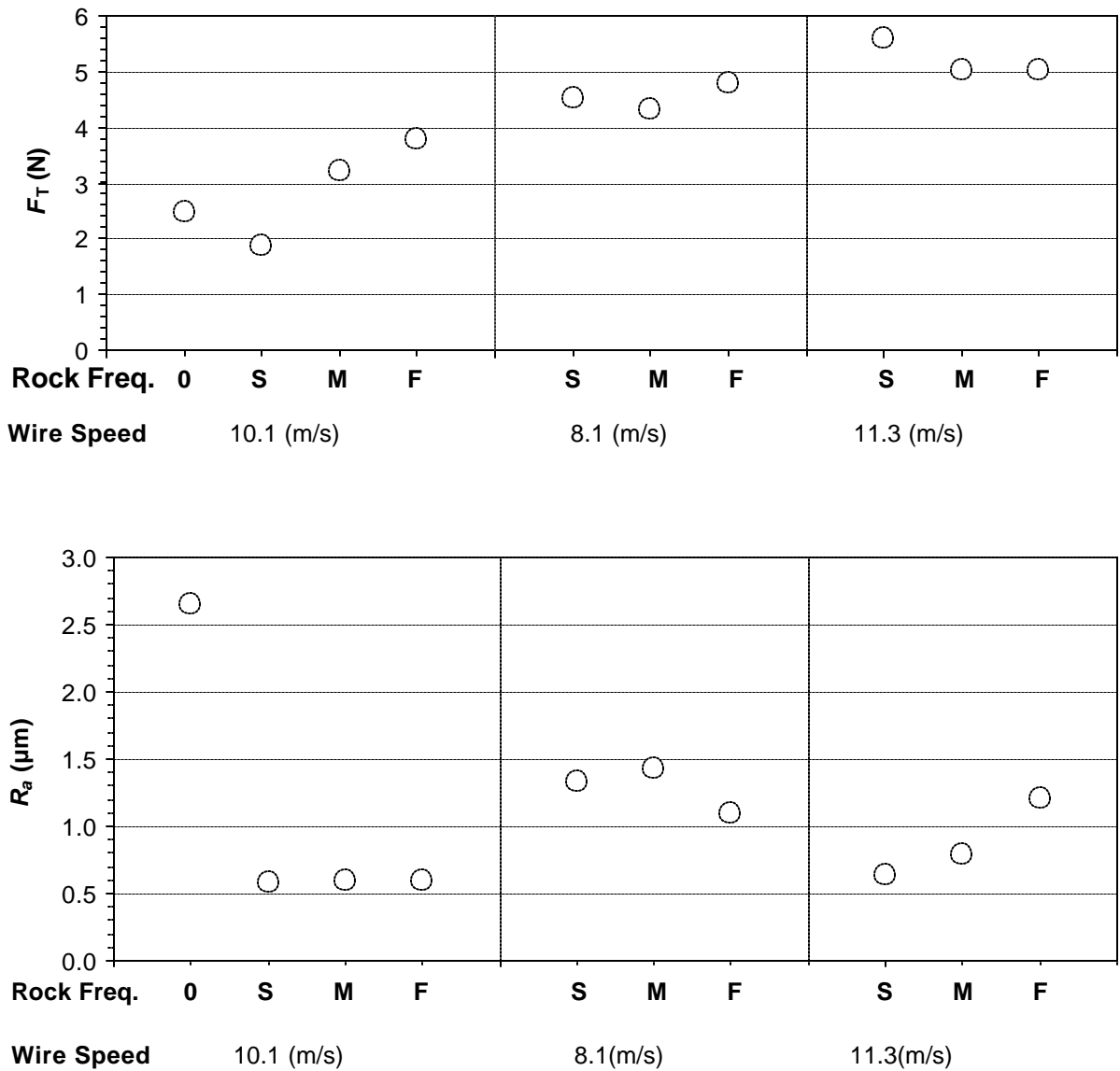


Figure 5.2 Single crystal SiC experiment II results.

The force plot above could be described as showing a process in which the wire is being broken in. There is a period in which the diamond abrasive wears greatly, and then becomes close to steady state for a period of time. That describes the initial low forces, then as the tests went on, the forces increased. The tangential force also shows the effects of the rocking motion. The first point in the force plot is a test that has no rocking motion. This point has

much higher forces than the next few cuts have. Therefore, the rocking motion and the kinematic analysis performed in chapter 3 is justified.

The wire speed was varied throughout experiment II, but the effects of the wire speed seemed to be overshadowed by the effects of the wire breaking in. The wire speeds were also varied by a small amount compared to some of the other parameters, which could also explain the negligible effects of wire speed.

The surface roughness results also showed some interesting trends. The first trend is that the rocking motion greatly affects the surface roughness. The  $R_a$  without rocking was close to 2.7  $\mu\text{m}$ , while the highest  $R_a$  with rocking motion was only 1.5  $\mu\text{m}$ . The surface roughness was the worst while machining the middle of the wafer, which could be explained by the coolant once again not reaching the cutting surface well. The middle of the wafer has the largest surface length, which means the coolant may not have saturated the area well. The best surface roughness obtained was about 0.59  $\mu\text{m}$ . This is not as good as the first test, but it is still acceptable.

Overall this test showed the phenomena of an abrasive breaking in. It also illustrated the importance of rocking motion on surface roughness. It finally illustrated that the rocking frequency did not appear to make a large impact on the force or surface roughness, but rocking motion was clearly important to obtaining a good surface roughness.

### **5.3 Scanning Electron Microscope Analysis**

Scanning electron microscopy is an excellent way to visually characterize the surface roughness due to machining. The SEM pictures in Appendix 1 show the three main types of surface damage, which were described in section 4.3. The three types of damage are

stagnation lines, microcracking, and surface pulverization. There is a large crack visible in A.1(b) and figure A.2(a), but it should be noted that that crack is a material defect, and was not caused by machining. Their test number refers them to the parameters of each experiment, which are listed above in Table 5.1.

The damage on this wafer is quite similar to the damage in the first experiment. All of the three types of damage were quite evident. The damage can be quite deep in some regions, such as in Figure A.2(b). Another interesting region is shown in Figure A.1(a). The first test was run with no rocking conditions, and the overall damage is very different than the test areas on the wafer with rocking conditions. The damage seems to be much worse, and the whole area seems pulverized. It appears as if the SiC was ripped out, and never machined. Overall the damage is very similar in type to the original test on the flat-sided wafer, but it differs in magnitude in certain areas.

## 6 Oscillatory Style Wood Machining Results

The main objectives of the oscillatory style wire saw testing were to try to investigate the cutting forces and to quantify the surface roughness. A higher speed cutting test was performed to see if the machine was capable of machining at faster feed speeds. The effects of a series of guide pulleys on the surface roughness and the cutting forces were also investigated.

### 6.1 Data Acquisition

The data acquisition system was used to acquire the cutting forces. This series of test used the force measurement system, except it was mounted on the linear feed mechanism. The normal force was calculated in a different manner than the single crystal SiC tests. The feed speeds were much faster than the diamond wire saw, so the force dynamometer was used to acquire all of the force data. Figure 6.1 below diagrams the cutting forces and their direction.

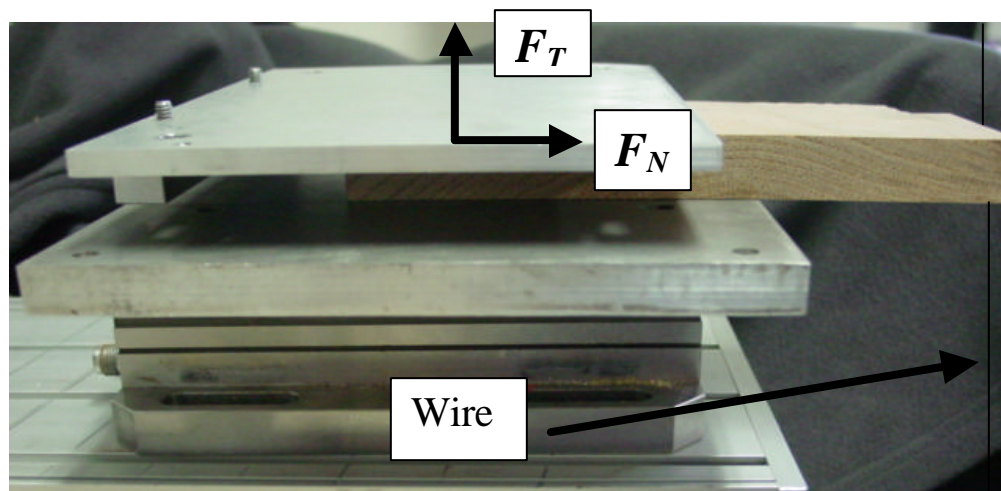


Figure 6.1: Wood machining force directions.

### 6.1.1 Tangential Force

The tangential force was acquired from the piezoelectric force dynamometer. The direction of the tangential force is normal to the dynamometer, and it had to be calibrated. Weights were placed on the dynamometer in a sequence of 0, 6, 12, 18, 24, 30, 36, 30, 24, 18, 12, 6, and 0 lbs. The plot below shows the voltage output due to the weights.

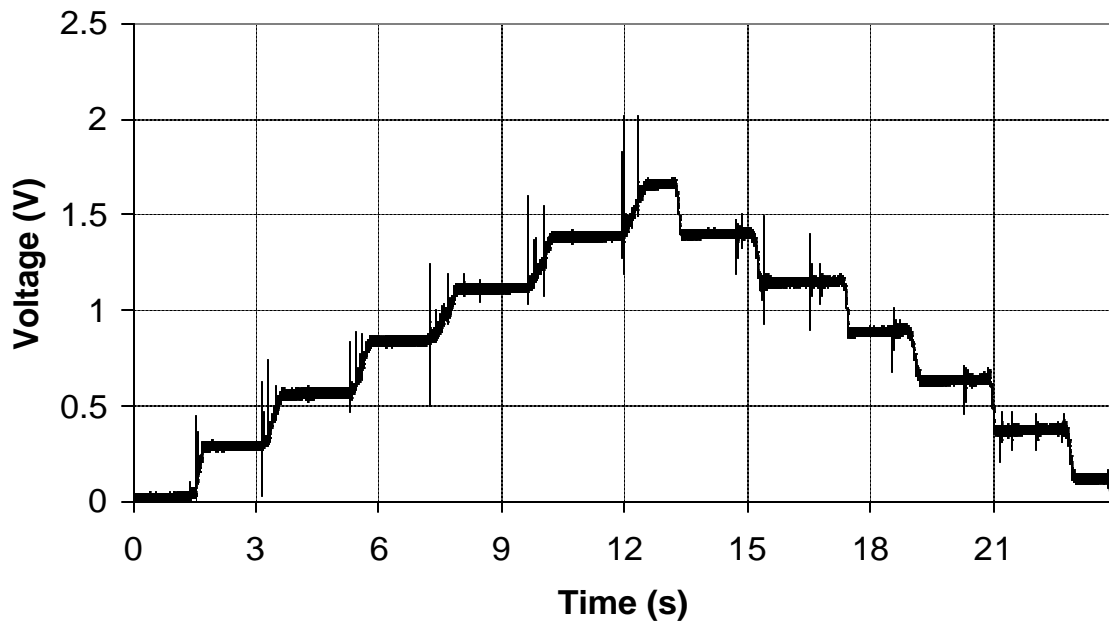


Figure 6.2: Tangential force calibration.

The calibration factor from above was found to be 0.009772 (V/N). It is evident that the end of the plot does not go back to zero voltage. This is due to a drift in the voltage. The experiments beforehand focused on the change in force when the wire changed directions, however the forces here are somewhat stagnant, and therefore the drift rate needs to be calculated.

The final challenge in calculating the tangential cutting force is calculating the drift rate of the charge amplifiers. Every charge amplifier has its own unique drift rate due to the set up of the circuitry and the nature of piezoelectric force calculation. The output of the whole data acquisition system was recorded while no forces were being applied to the dynamometer. The plot below shows the overall drift rate of the data acquisition system.

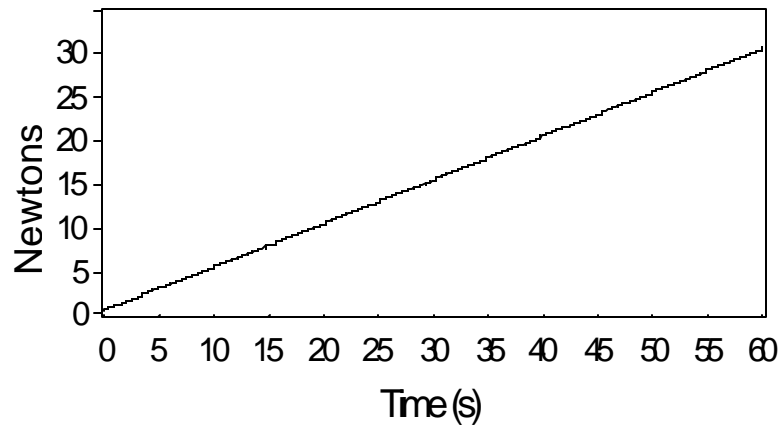


Figure 6.3:  $F_T$  drift rate plot

After the drift rate was determined,  $F_T$  could be calculated. A moving average was performed again, to remove unnecessary noise that is inherent in the data acquisition system.

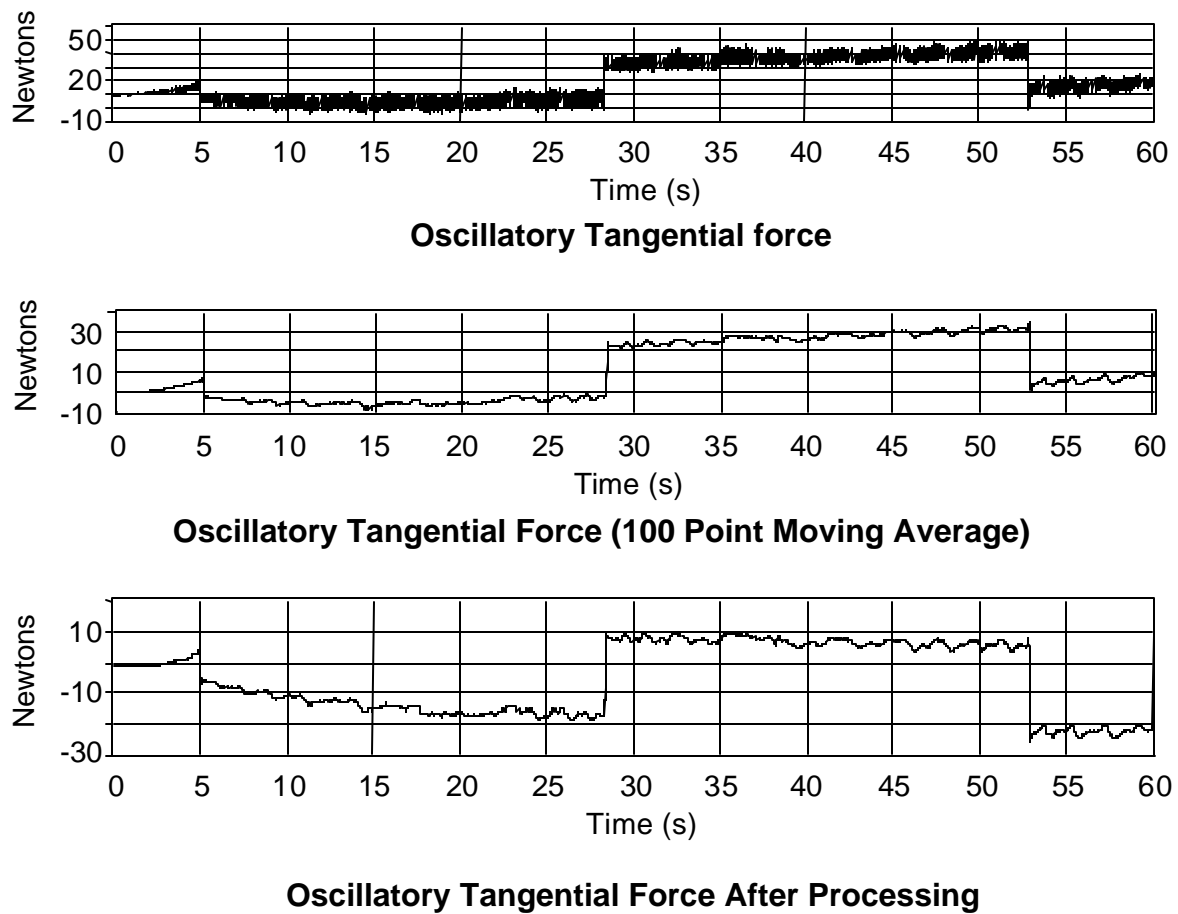


Figure 6.4 Oscillatory wire saw data.

The final step in the force analysis process was to convert the force to a specific force. The method used is exactly the same as what was described in section 4.1.1. The only difference is that  $t$ , the workpiece thickness is 19.05 mm, and  $W_D$ , the wire diameter was 0.5 mm.

### 6.1.2 Normal Force

The normal force,  $F_N$ , was calculated with similar methods to  $F_T$ . The dynamometer was calibrated, and so was the drift rate. It was acquired in the exact same method that was explained in section 5.2.1. Figure 6.4 shows a typical tangential force during the second experiment.



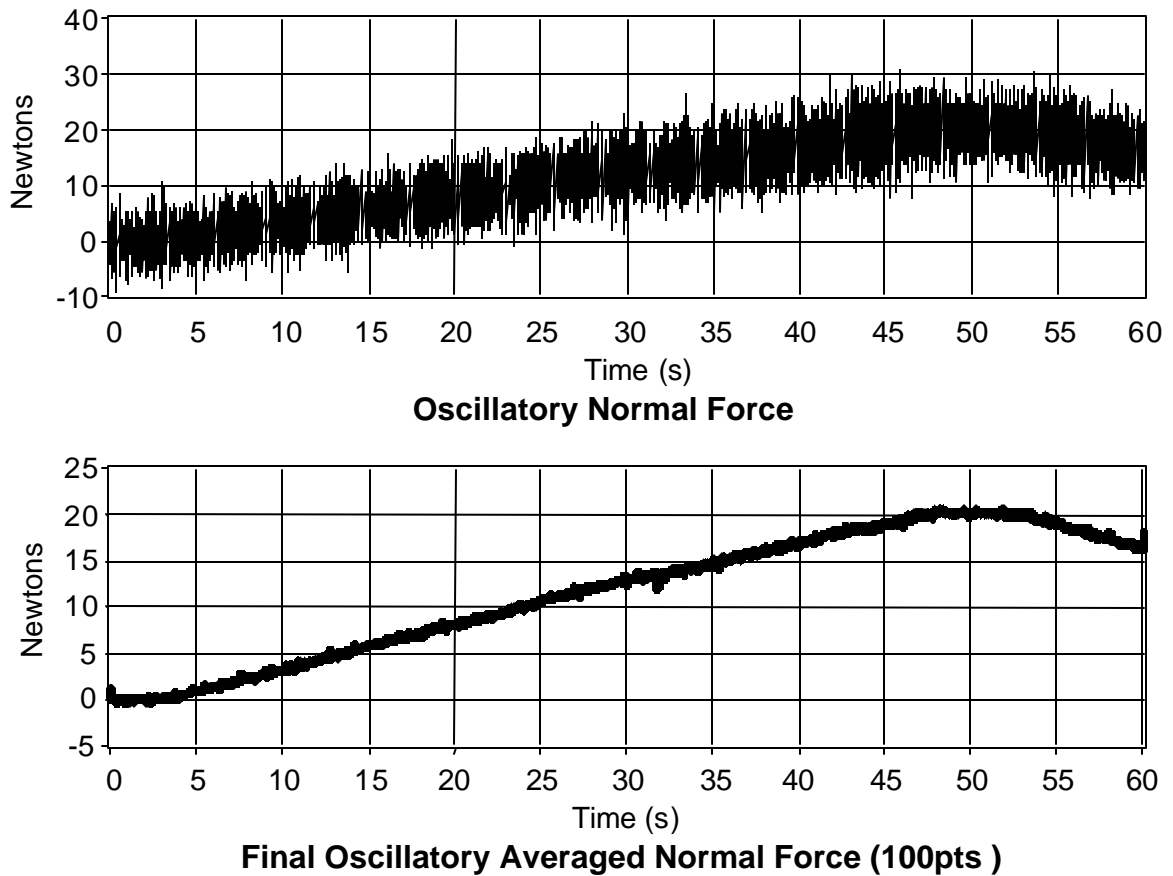


Figure 6.5 Oscillatory wire saw normal force.

The flat peak is where the cut reached steady state, and the force tapered off after the slide stopped moving forward. The final process in the analysis process was to convert the force to a specific force. This method was discussed in sections 5.2.1 and 6.1.1.

## 6.2 Cutting Force and Surface Roughness Results

The experiment was set up to see the effects of feed speed, wire speed on cutting forces and surface roughness. A separate test was run to see the effects of feed speed on cutting

forces. The machine's capabilities were taken to the limits during the testing and the following test matrix sums up the experiments run on the oscillatory wire saw. Tables 2.5 through 2.7 describe the process parameters in the experiments. After all of the data was processed, and the surface roughness was evaluated, the following results were tabulated in Figure 6.6.

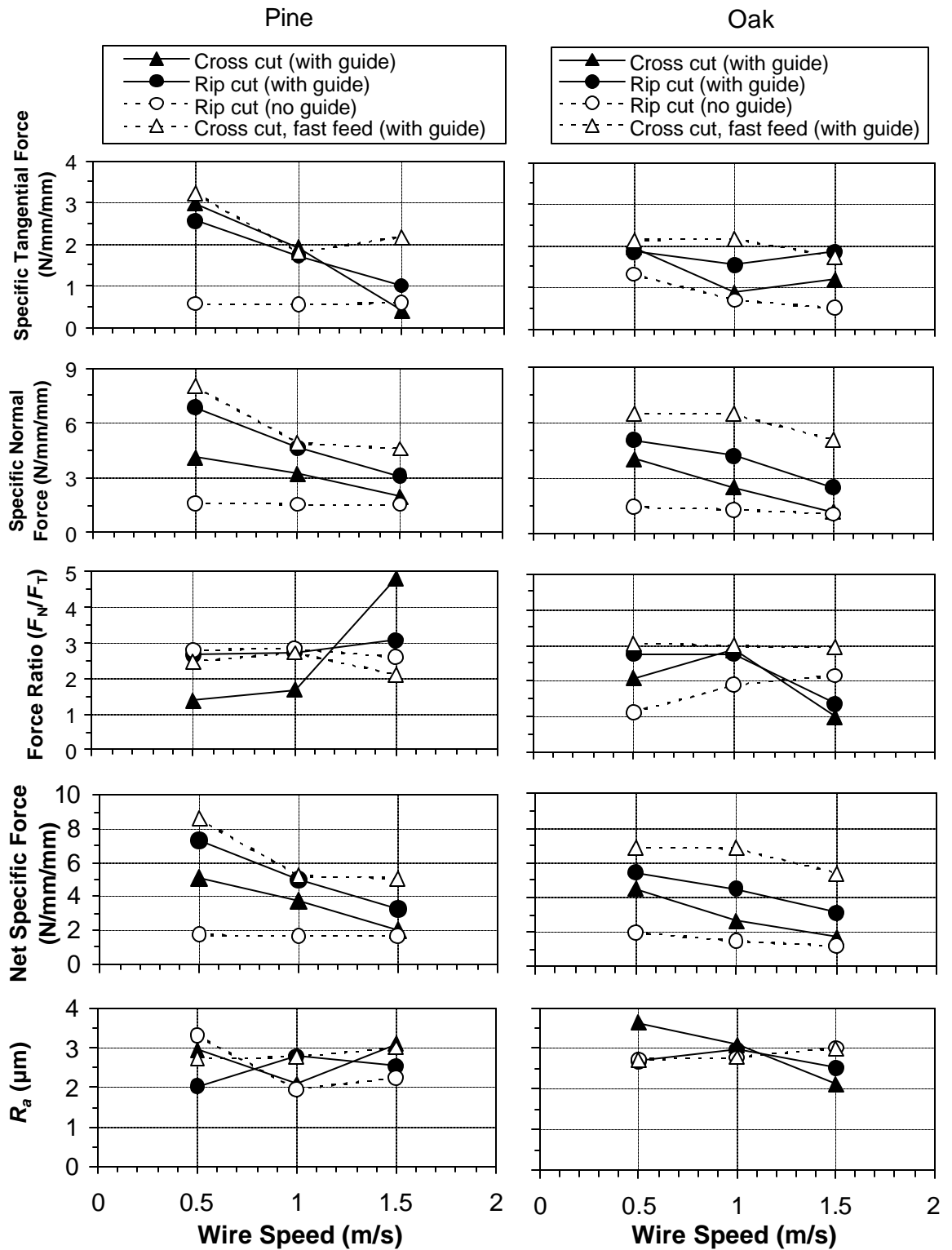


Figure 6.6 Oscillatory force and surface roughness results.

### 6.2.1 Baseline Results

The baseline tests in this experiment show the differences between a rip cut and a cross cut with guide pulleys. The rip cut and cross cut had very similar specific tangential forces,  $f_T$ . They both linearly decreased with a linear decrease in wire speed. The Pine workpieces had a larger linear decline with the wire speed, but overall both species showed similar trends. This was expected, and goes with conventional theory.

The specific normal forces,  $f_N$ , gave different force results. The specific normal force decreased linearly with a linear increase in wire speed. The pine cross cut tests had almost half the specific normal forces than the rip cut. The oak had similar trends, but it did not have as large of a difference between the two cuts. Overall  $f_N$  was much higher than the  $f_T$ . This is due to the combination of feed rate and wire speed.

The force ratio did change, but not to a large degree. The pine ratio stayed from 0.35 to 0.65. This demonstrated that the cutting was effective, and is similar to the results that Clark [9] reported while machining wood with diamond wire.

The net specific force showed a definite correlation to the wire speed. The rip cut in both pine and oak showed a magnitude much higher than a cross cut. This could be due to the difference between cutting across the grain verses cutting with the grain.

The surface roughness did not show much a correlation with wire speed or feed speed. It basically stayed within a range of 2 to 3  $\mu\text{m}$ . The surface is far better than cuts made on a band saw, which could not be read on the surface profilometer.

## 6.2.2 Guide Pulley Test Results

The first experiment showed the effects of the guide pulleys. The rip cut performed had much a much lower  $f_N$ . The observation is that the wire guides cause the force to be transmitted to the workpiece rather than dissipated by deflecting the wire. This is desirable because wire deflection creates less precision in the cutting, and also slows the cutting greatly. The forces were lowered, but the cutting was neither efficient nor desirable.

The specific normal forces were also much lower without the guides. This was due to the same explanation given above, and the wire deflected a large amount.

The force ratio was quite similar to every other cut, and basically stayed constant during the machining process. The ratio was not affected by cutting speed or wire speed.

The wire guide pulleys did not affect the surface roughness. The surface roughness stayed within the 3 to 4  $\mu\text{m}$  level. The oak and pine specimens showed similar trends in surface roughness.

## 6.2.3 Higher Feed Speed Test Results

The second experiment showed the effects of a higher feed speed on a cross cut. The specific normal force was much higher at the higher feed speed, which would be expected. The pine results were quite similar to the lower speed rip cut. The oak results were quite similar as well. The wire speed did lower the tangential forces, but not at the same rate as the slower feed speed.

The specific normal force was affected by the feed speed in a similar manner as the tangential force. The  $f_N$  was very similar to the rip at the slower feed speed as well. The

wire speed lowered the normal forces, but with a much smaller slope. The oak and pine results were quite similar.

The force ratio was once again similar to lower feed speeds, and there does not seem to be a correlation from feed speed to force ratio.

The net specific force was quite similar to the rip cut in both pine and oak. The forces were overall a small amount higher, but it was only about a 10% increase at most.

The surface roughness was not affected by the elevated feed speed. This is quite encouraging, because it shows that feed speed can be elevated without sacrificing the surface roughness values.

## **7 Looped Style Wood Machining Results**

The main objectives of the looped style wire saw testing was to try to investigate the cutting forces and to quantify the surface roughness. Two basic tests were performed; one looked at the effects of coolant over a range of cut types and feed speeds. The other investigated the cutting speed limits of the looped wire saw.

### ***7.1 Data Acquisition***

The exact same data acquisition method and system was used in the oscillatory style experiments, which was described in section 6.1.1 and 6.1.2.

### ***7.2 Cutting Force and Surface Roughness Results***

The experiment was set up to see the effects of feed speed and coolant on a number of different types of cuts. A separate test was run to see the effects of high feed speed on cutting forces. The machine's capabilities were taken to the limits during the testing and the following test matrix sums up the experiments run on the oscillatory wire saw. The test matrices are shown in Tables 2.8 through 2.10. After all of the data was processed, and the surface roughness was evaluated, the following results were tabulated. Figure 7.1 shows the baseline data as well as the coolant tests. Figure 7.2 shows the high feed speed cross cut test on pine.

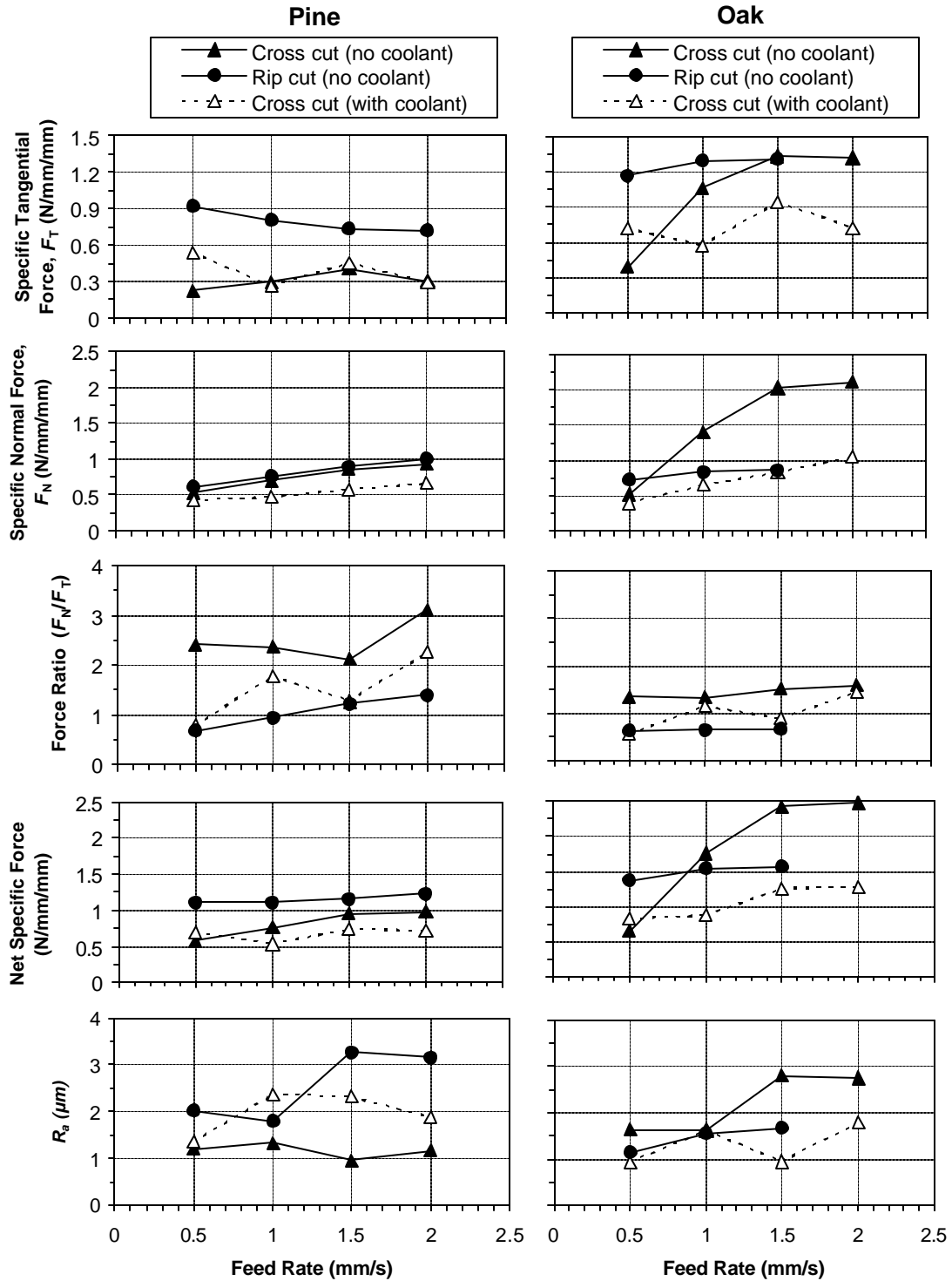


Figure 7.1 Oscillatory force and surface roughness results of baseline and coolant tests.



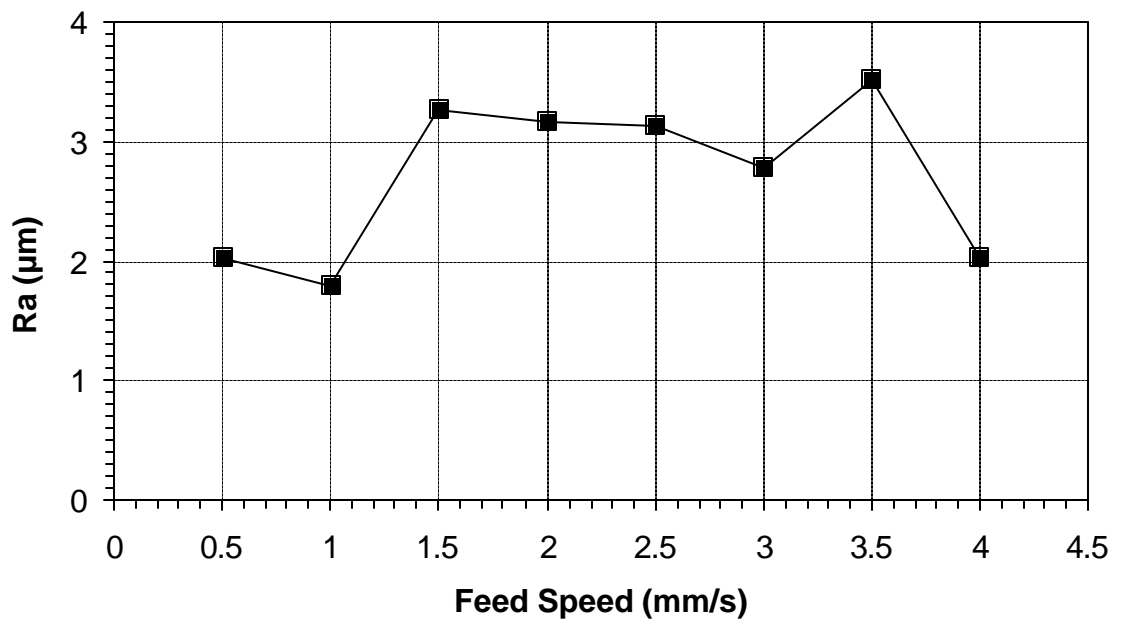
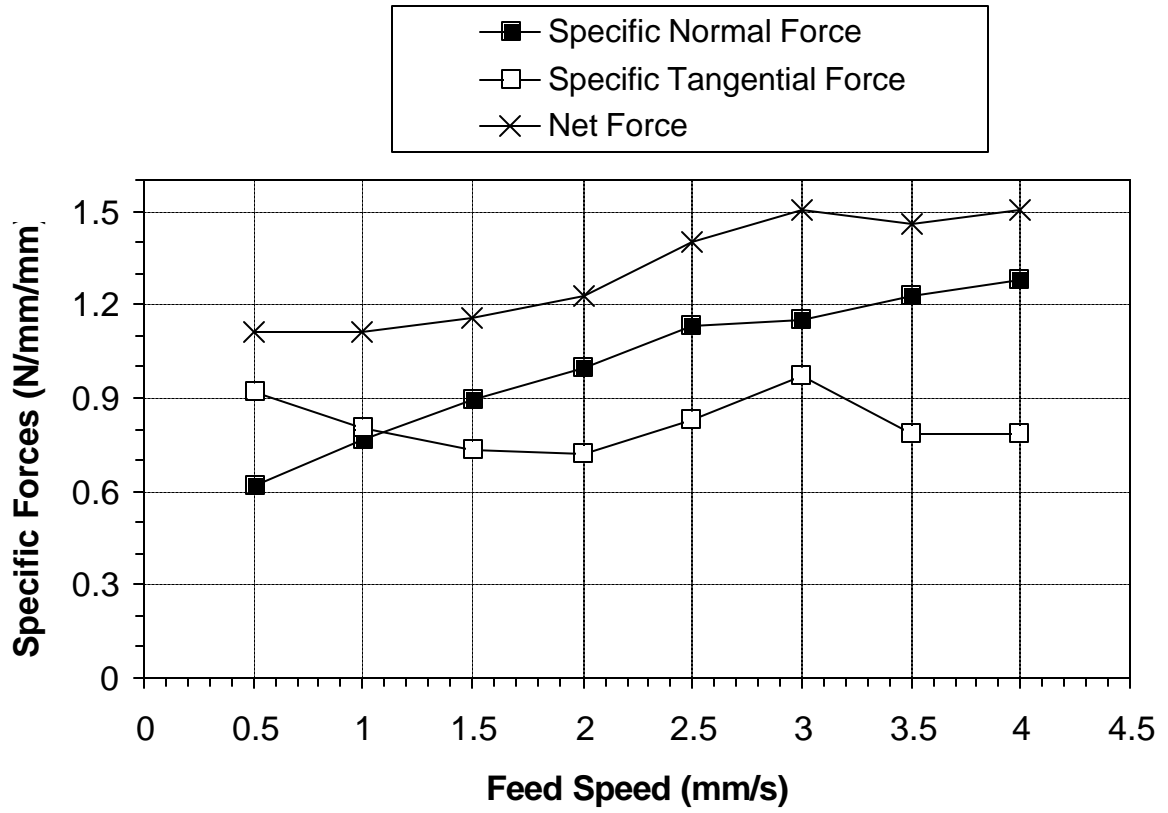


Figure 7.2 Oscillatory force and surface roughness results of high feed speed test.

### 7.2.1 Baseline Results

The first set of plots in Figure 7.1 display the specific tangential forces. They show some very interesting trends. The first trend is that an increase in feed speed definitely decreases  $f_T$ . This is what would be expected with conventional machining. The second observation is that a rip cut with diamond wire requires much more force. This is a trend that is appearing in all experiments. This is most likely due to the grain microstructure of the wood. The most interesting part of the plot showed decidedly that pine had lower machining forces overall. This might be due to the fact that some of the pine came out almost charred looking, which means that the wood was heating up a lot, and machining faster because of this.

$f_N$  showed many of the same trends that the specific tangential force showed. The cross cut once again showed a much lower normal cutting force. The increased feed rate also increased the machining forces, which is to be expected.

The force ratio showed that the cutting was quite effective. It has ratios similar to those that Clark [9] investigated in his wood machining experiments. The pine force ratios seemed to increase slightly with the increase in feed speed. The oak force ratios varied more during the experiments, but they still showed fairly efficient cutting was taking place.

The net specific force shows how the overall force magnitude changes. It basically shows the same principles involving the feed speed. The feed speed increased the forces, and the rip cut had much higher forces overall.

The surface roughness is also very interesting. Every one of the tests performed all had a surface roughness within 1 to 3.5  $\mu\text{m}$ . The feed speed seemed to slightly affect the surface roughness, but it was not totally detrimental. The most important fact is that the surface

roughness of this wood is magnitudes better than wood machined on a band saw. The surface roughness could not be read properly on the surface roughness analysis tools used.

Overall the experiment showed many interesting trends, but also validated many trends that were expected. One interesting note is that oak could not sustain a rip at the highest feed speed. The experiment was started, but was stopped quickly to preserve the looped wire saw.

### **7.2.2 Coolant Test Results**

The coolant decreased the tangential specific cutting forces, especially in the oak experiments. The pine tangential forces didn't respond the same, but the overall trend is positive. They still show the same trends that the dry tests ran, but the force is lower overall.

The specific normal cutting force also decreased when coolant was applied. Both oak and pine normal cutting forces were reduced with the usage of a small amount of coolant.

Overall the coolant also lowered the net forces, which is also to be expected. The specific normal and tangential forces were lowered; therefore the magnitude was lowered as well.

The coolant did seem to improve the surface finish as well. It could be explained as something like a wet sanding process, where water acts as a lubricant. It could also be explained by keeping the wire cooler, which allowed it to cut as it was designed.

### **7.2.3 Feed Speed Test**

The second high feed speed cross cut on pine showed interesting results. The test showed the limits of the feed speed with the looped wire saw. These results show that a much higher feed speed can be used with a looped wire test. The forces increased while the feed speed increased, which was expected.

The high feed speed test also showed that the surface roughness is not compromised while machining at high speeds. They were somewhat higher, but overall they were quite acceptable. This experiment shows that the looped wire saw is superior in cutting speed and the surface roughness is not compromised, which is desirable.

## 8 Conclusion

With increasing material costs for wood materials, there exists a need for a method of machining with lower kerf loss. Fixed abrasive diamond wire saw machining was investigated for use in cutting wood. Wood machining is traditionally dominated by the use of steel saw blades. The fixed abrasive diamond wire developed for use by the semiconductor industry to slice crystal ingots is significantly thinner than even the most advanced thin kerf saw blades. This can lead to significant material cost savings in a production environment.

Single Crystal SiC is extremely difficult to machine. The current production methods are quite time consuming and costly. As demand grows for power and optoelectrical devices built on this substrate, the demand for faster and more effective machining methods grows as well. Fixed abrasive diamond wire stands to be a possible method to meet these needs, and the need for research in this field is very large.

The machining properties of single crystal SiC were examined. The effects of wire speed, feed speed, and rock frequency on surface roughness and cutting forces were explored. The first experiment showed that the cutting forces were directly correlated with surface roughness. It also showed that downfeed rate does not affect the surface roughness, but it does the depth of damage in the wafer. A hypothesis was made about the surface roughness being directly related to the amount of coolant that comes in contact while cutting. This hypothesis also helped to explain the tangential cutting forces. The scanning electron microscope micrographs provided a visual characterization of the damage. The formation of

stagnation lines was found to be due to a slowdown in wire speed, but no slow down in downfeed rate. The surface roughness was within a range of 0.2 to 0.3  $\mu\text{m}$ .

The second SiC machining experiment examined the surface roughness and tangential forces of a complete silicon wafer being machined with new diamond wire. This experiment showed the effects of breaking in a new wire, and the surface roughness associated with that process. It also examined the effects of rocking frequency on surface roughness. The portion of the wafer made without rocking motion was found to have a much worse surface roughness. The presence of rocking motion was found to affect the surface roughness more than the actual value of the rock frequency.

The oscillatory wood machining experiment showed that wire speed plays a large roll in the forces. The ability of a wire saw to machine at high feed speeds was found to be dependent on the wire speed. The effects of having wire guides that keep the wire from deflecting were also investigated. The wire guides appeared to keep the wire from deflecting, but did increase cutting forces. The overall outcome is that the oscillatory saw machines wood well at slow feed speeds, but the feed rate was still slow compared to the ones achieved by the looped wire saw. The surface roughness was found to be 2 to 3  $\mu\text{m}$ , which is extremely good for wood products.

The looped high wire speed saw was found to be able to maintain the fastest feed speeds of any wire saw investigated. The wire ran at close to 13 times the feed speed that the oscillatory wire saw operated at. The maximum feed rate was found to be 4 times faster than the oscillatory saw. The surface roughness was in the range of 3 to 4  $\mu\text{m}$ , which was a little worse than the oscillatory saw, but is still magnitudes better than any other wood machining method.

In conclusion there is still a large amount of research left to be performed in the fixed abrasive wire saw field. The effects of the rock angle should be investigated while machining single crystal SiC. The controller in the Millennium Series Slicing Saw should be modified to be able to slow down the downfeed while the wire is reversing direction. The coolant delivery system should also be investigated to see if there is any way to improve the coolant flow. Finally a new series of tests should be run to investigate the surface roughness after these modifications.

The wood machining results showed that there is also a need for more research in this field. A machine with a higher wire speed than 20 (m/s) should be found and investigated for wood machining. The feed rates in the looped wire saw were much higher than explored elsewhere, but are still nowhere near the capabilities of conventional thin kerf saws.

Overall the findings are quite informative, and can stand as a great place to start for further experiments.

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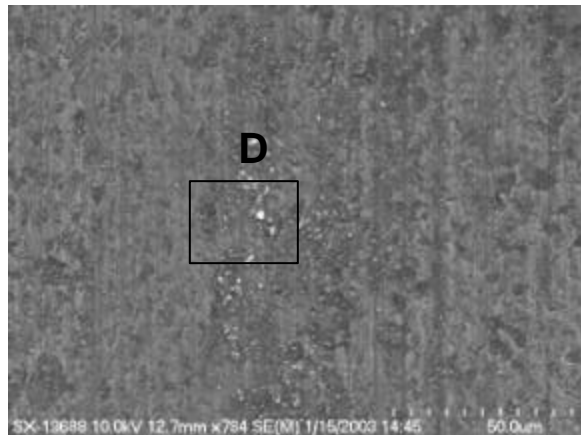
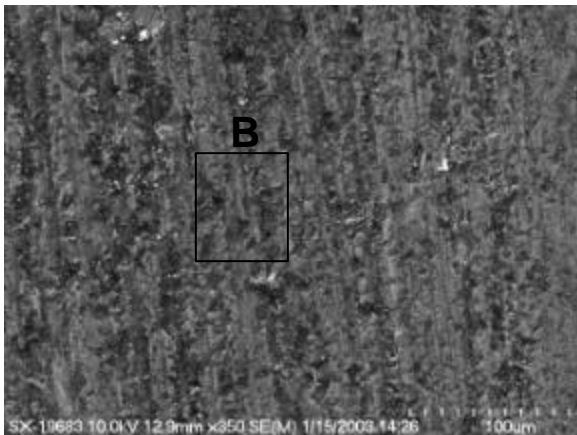
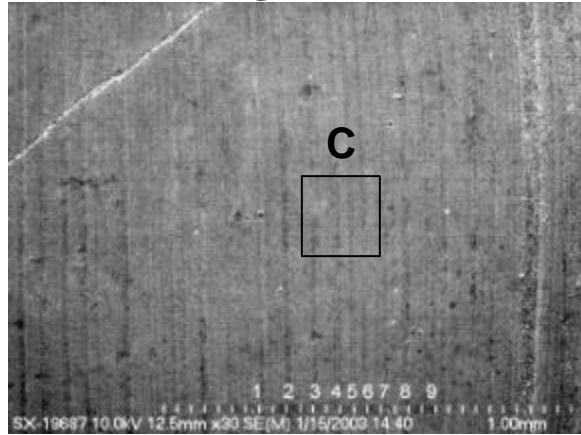
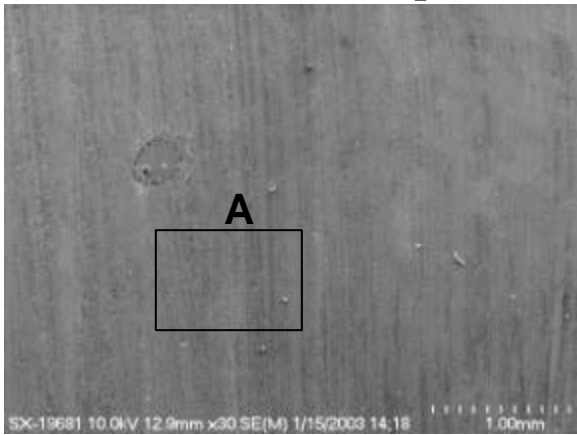


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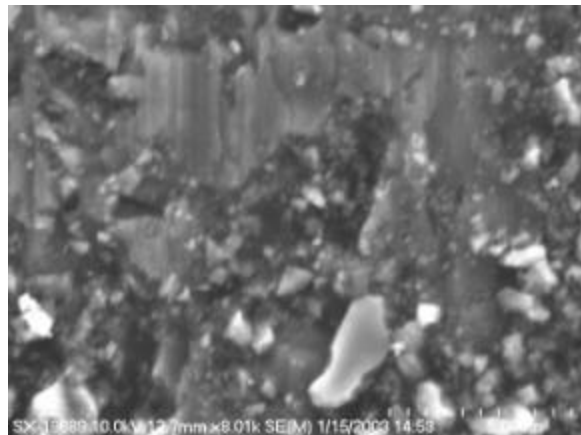
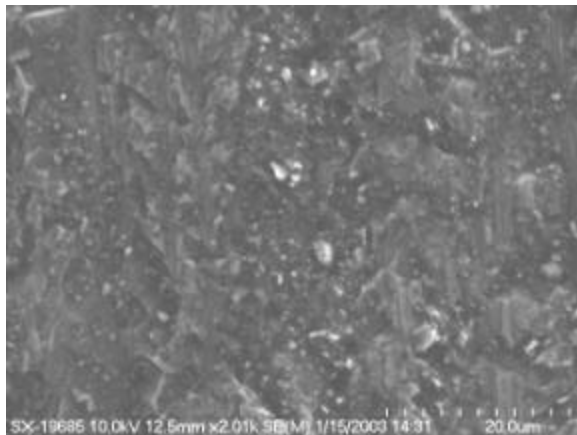
# Appendix A

## Experiment II SEM Catalog



Close-up of A

Close-up of C



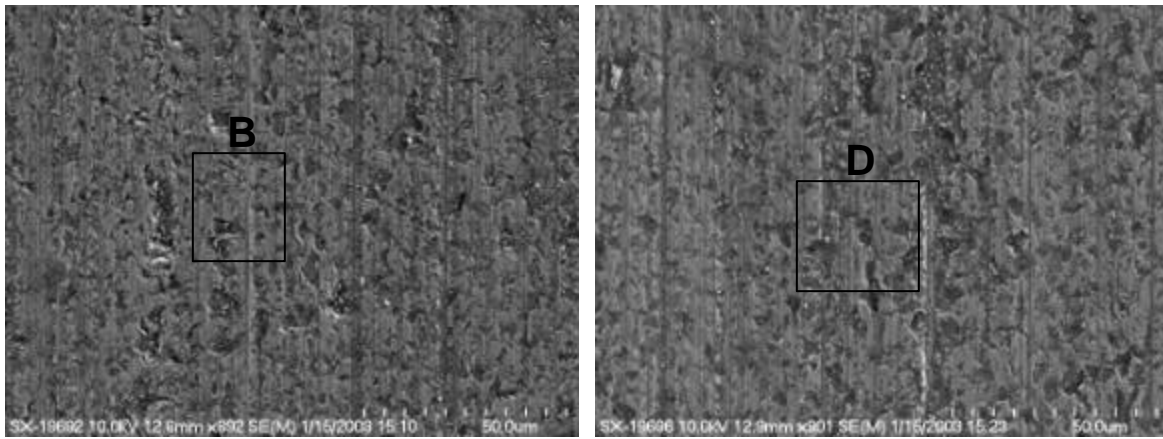
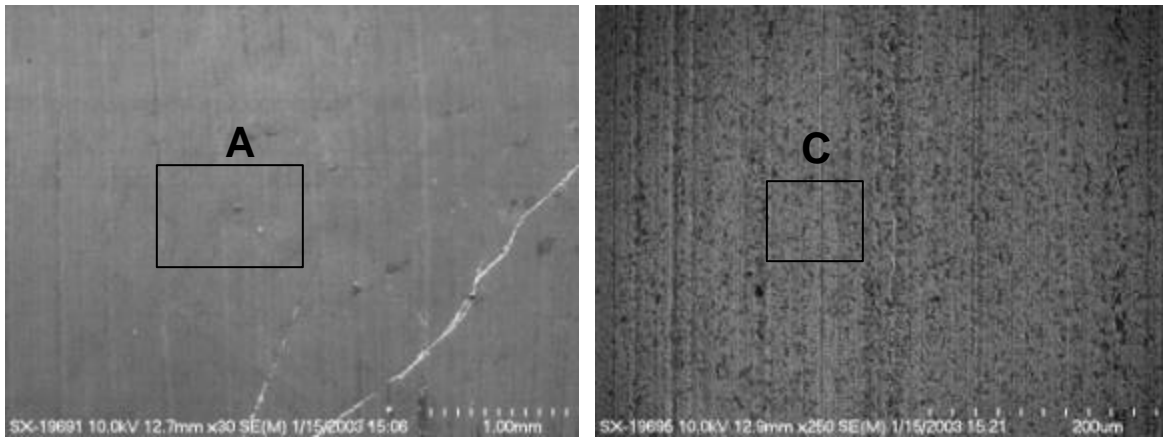
Close-up of B

Close-up of D

(a)

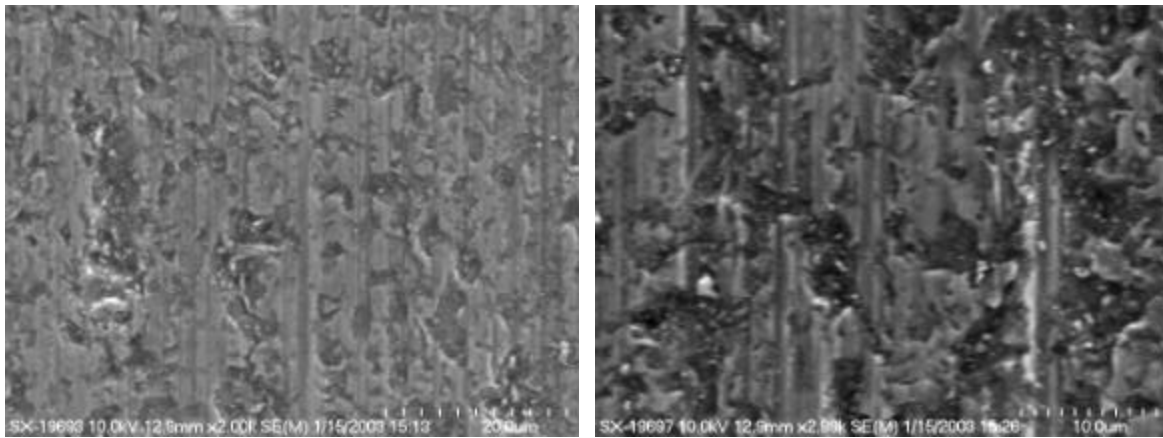
(b)

A.1: SEM micrographs of machined SiC surface machined of (a) test 1 and (b) test 2



Close-up of A

Close-up of C



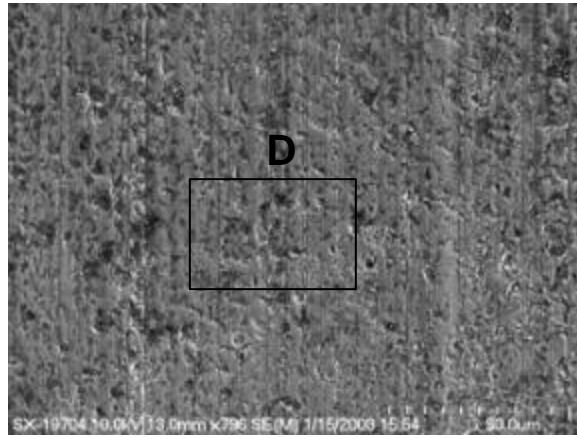
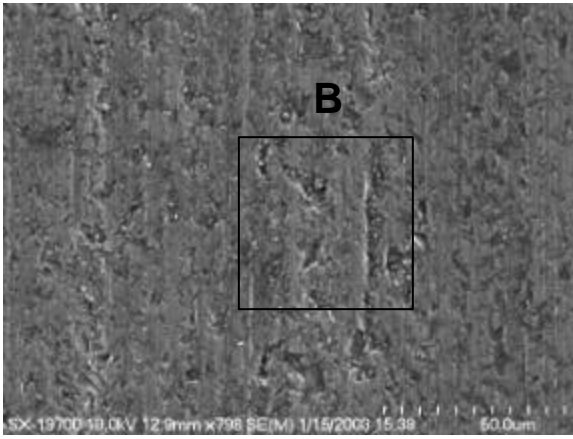
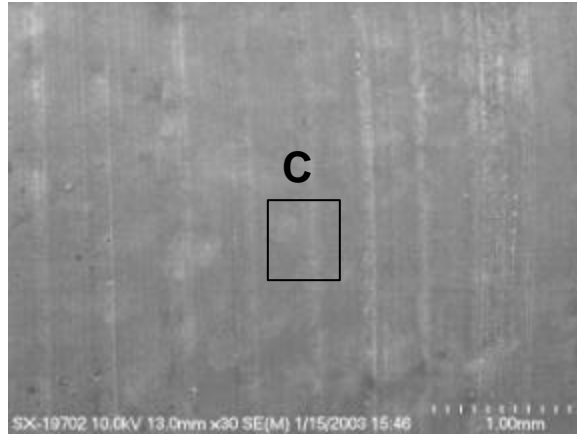
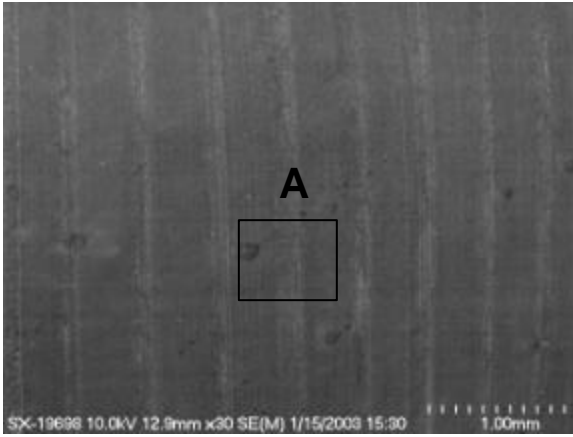
Close-up of B

Close-up of D

(a)

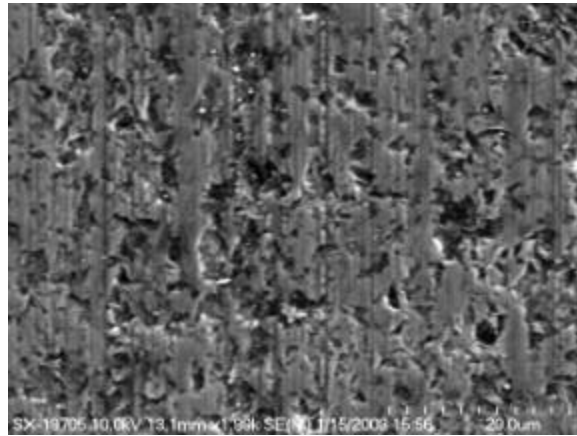
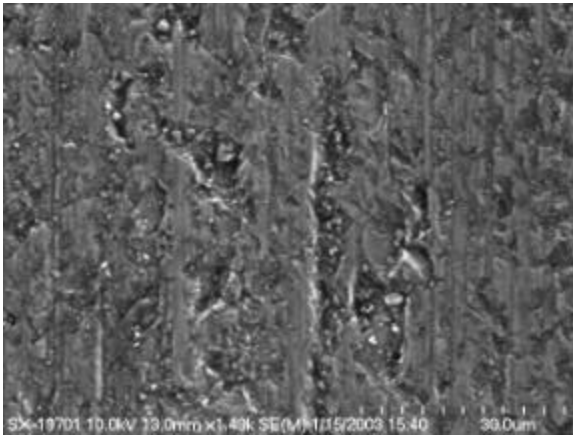
(b)

A.2: SEM micrographs of machined SiC surface machined of (a) test 3 and (b) test 4



Close-up of A

Close-up of C



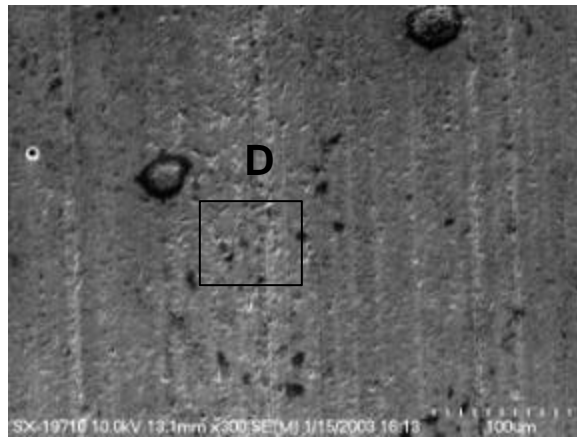
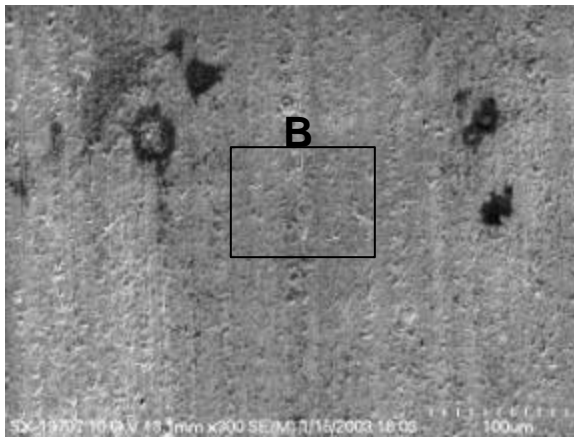
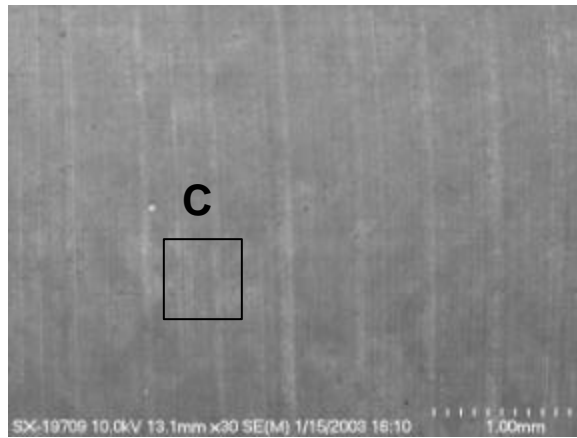
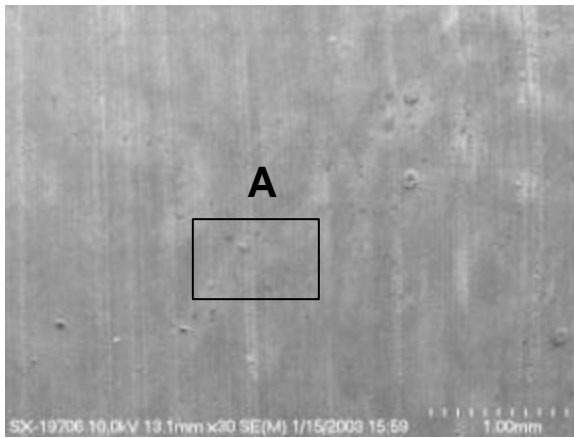
Close-up of B

Close-up of D

(a)

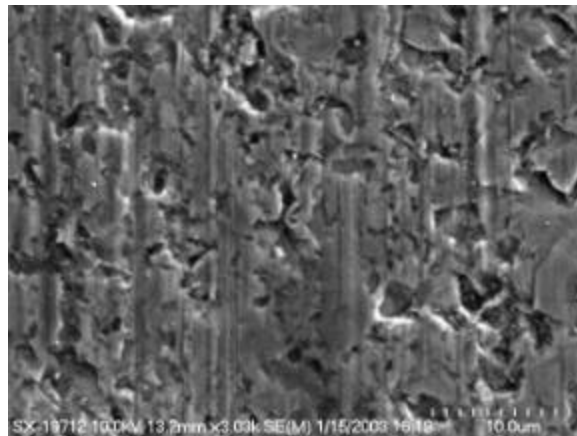
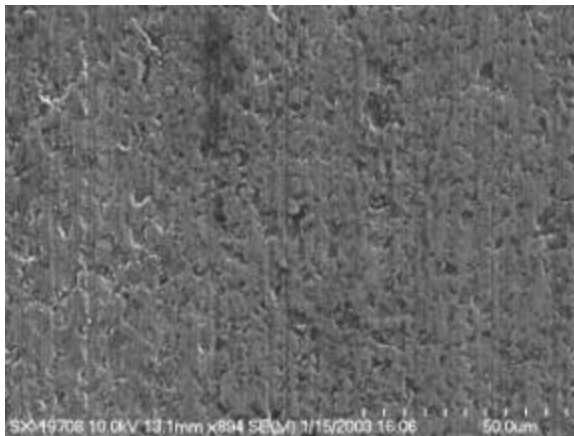
(b)

A.3: SEM micrographs of machined SiC surface machined of (a) test 5 and (b) test 6



Close-up of A

Close-up of C



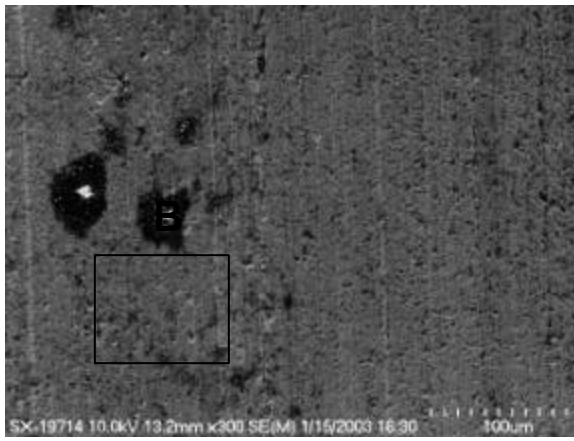
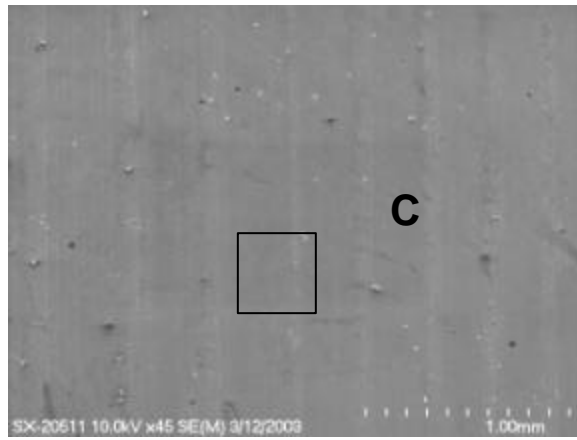
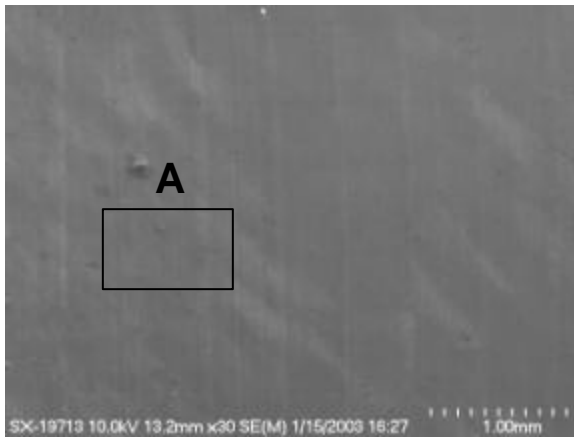
Close-up of B

Close-up of D

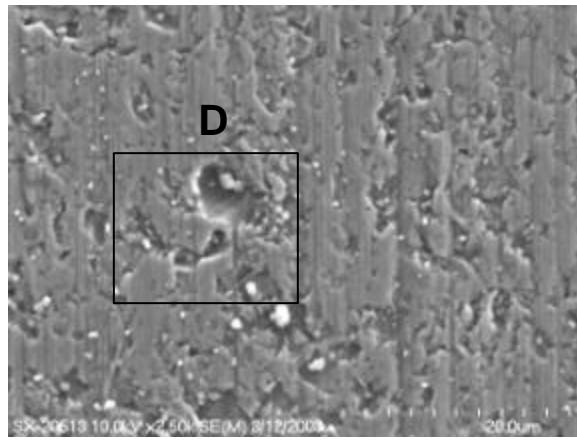
(a)

(b)

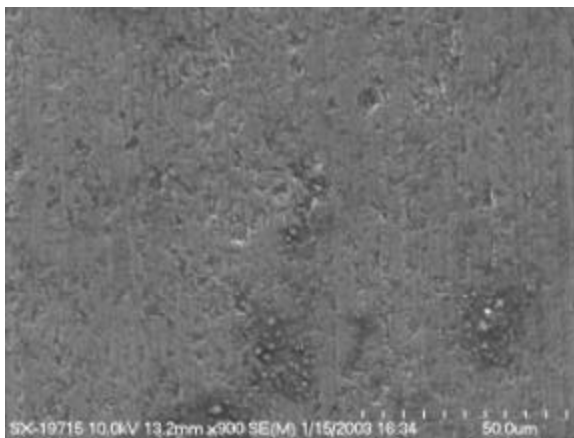
A.4: SEM micrographs of machined SiC surface machined of (a) test 7 and (b) test 8



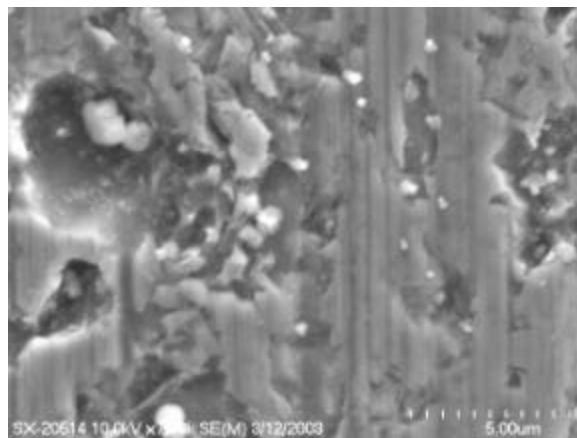
Close-up of A



Close-up of C



Close-up of B



Close-up of D

(a)

(b)

A.5: SEM micrographs of machined SiC surface machined of (a) test 9 and (b) test 10